

BIOSTEC 2016

9TH INTERNATIONAL JOINT CONFERENCE ON
BIOMEDICAL ENGINEERING SYSTEMS AND TECHNOLOGIES

21 - 23 FEBRUARY, 2016

ROME, ITALY



Organic bio-electronic sensors for ultra-sensitive chiral differential detection



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Basilica di San Nicola



Bari

The University o
“A.Moro”



Puglia

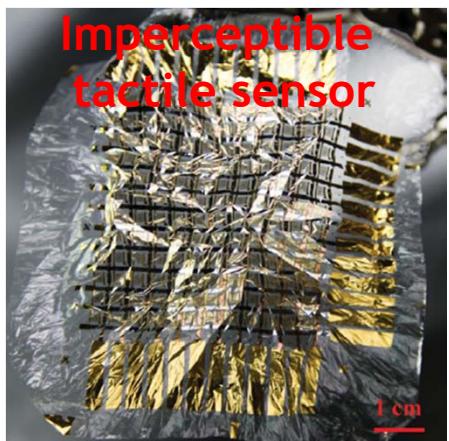
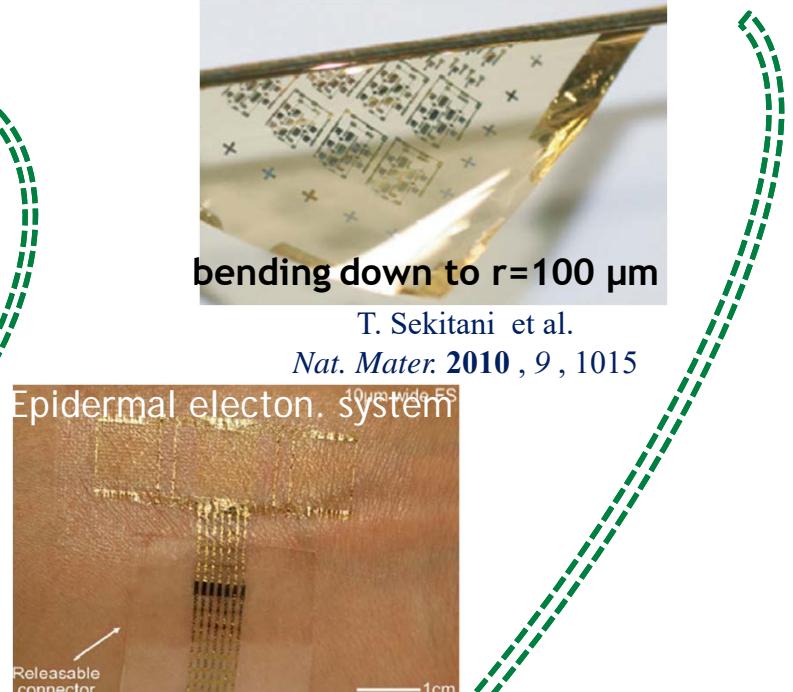


outlook

- ① developing and applying new methods for early diagnostics / PoC
- ② printable bio-electronic field-effect transistors
- ③ detections down to fM, chiral differential detection with an ESF > 6
- ④ Odorant Binding and anti-C Reactive Protein as cases of study



printable electronics



minority report – Steven Spielberg (2002)



Luisa Torsi - Università degli Studi di Bari “Aldo Moro” (Italy)

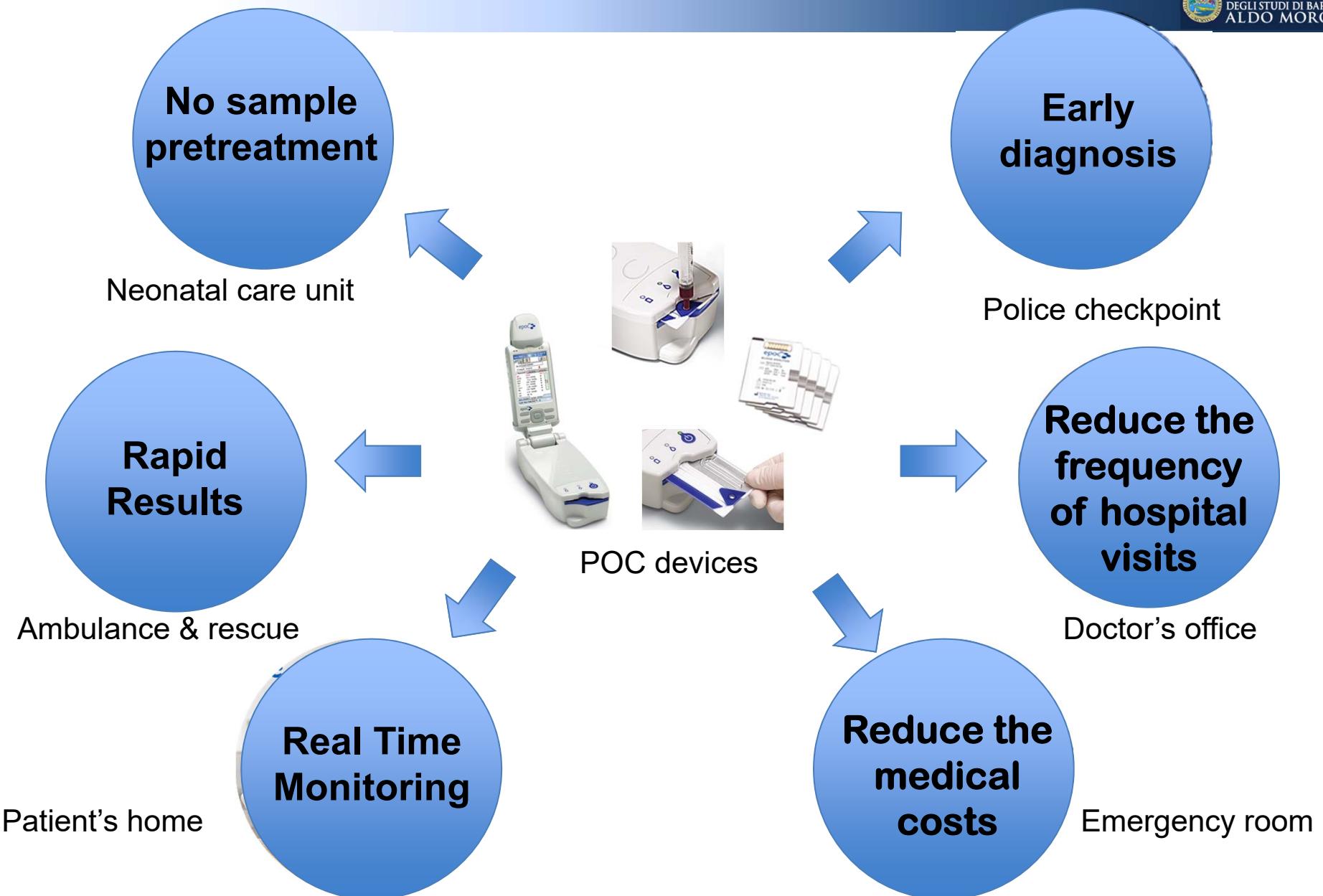
SAMSUNG Flexible AM OLED



<https://www.youtube.com/watch?v=-k6r2HQY9Ws>

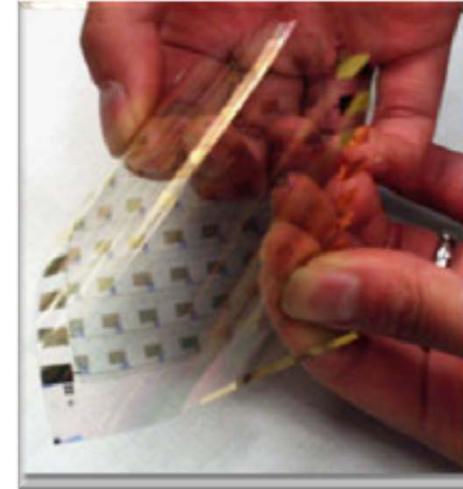
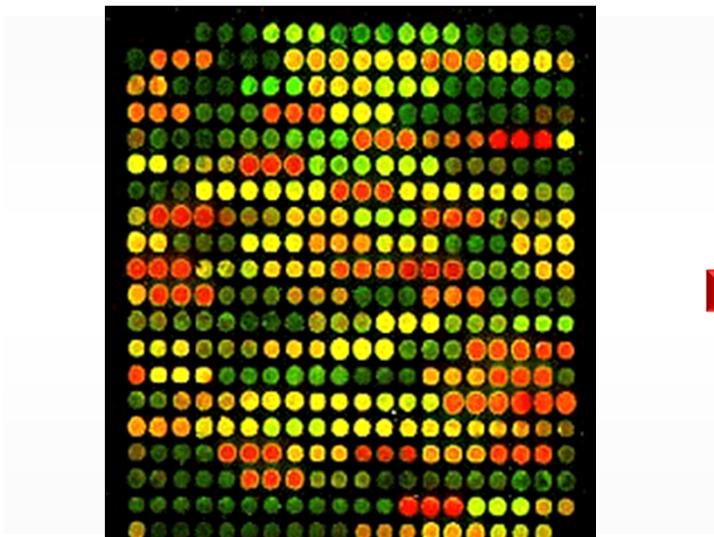


point-of-care biosensors



sensing arrays: this is the way to go

Affymax DNA chip



http://bmel.korea.ac.kr/image/intro_fig_5_4.gif

Label-free

*Low cost, low power, disposable electronic sensing system
Implemented on flex substrate (plastic, fabric, paper)*

optical and electrochemical method



PROS

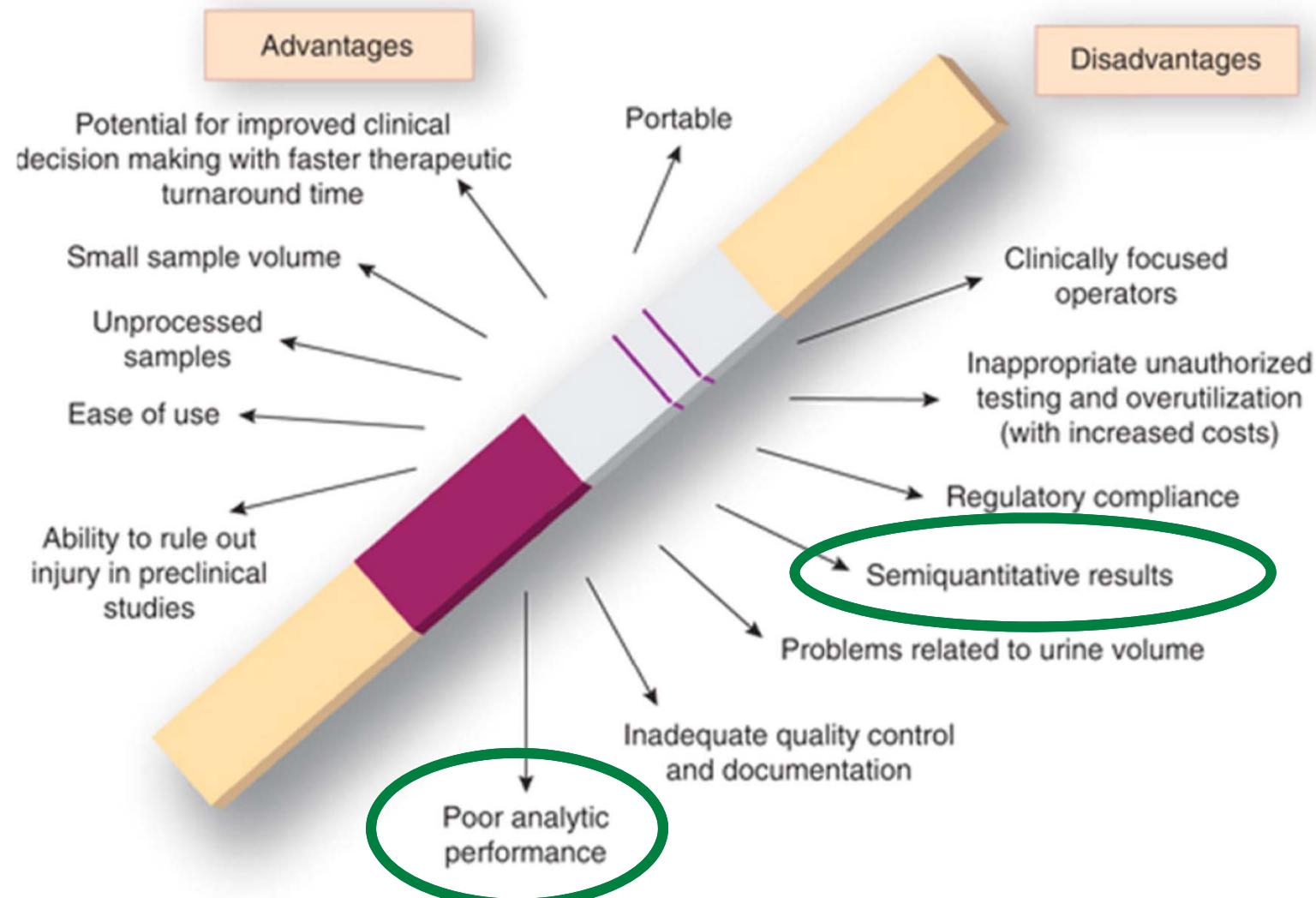
- *Easy miniaturization*
- *CMOS compatible (no reference electrode)*
 - *Label-free*
- *Low cost (printing fab on plastic, fabric, paper)*



CONS

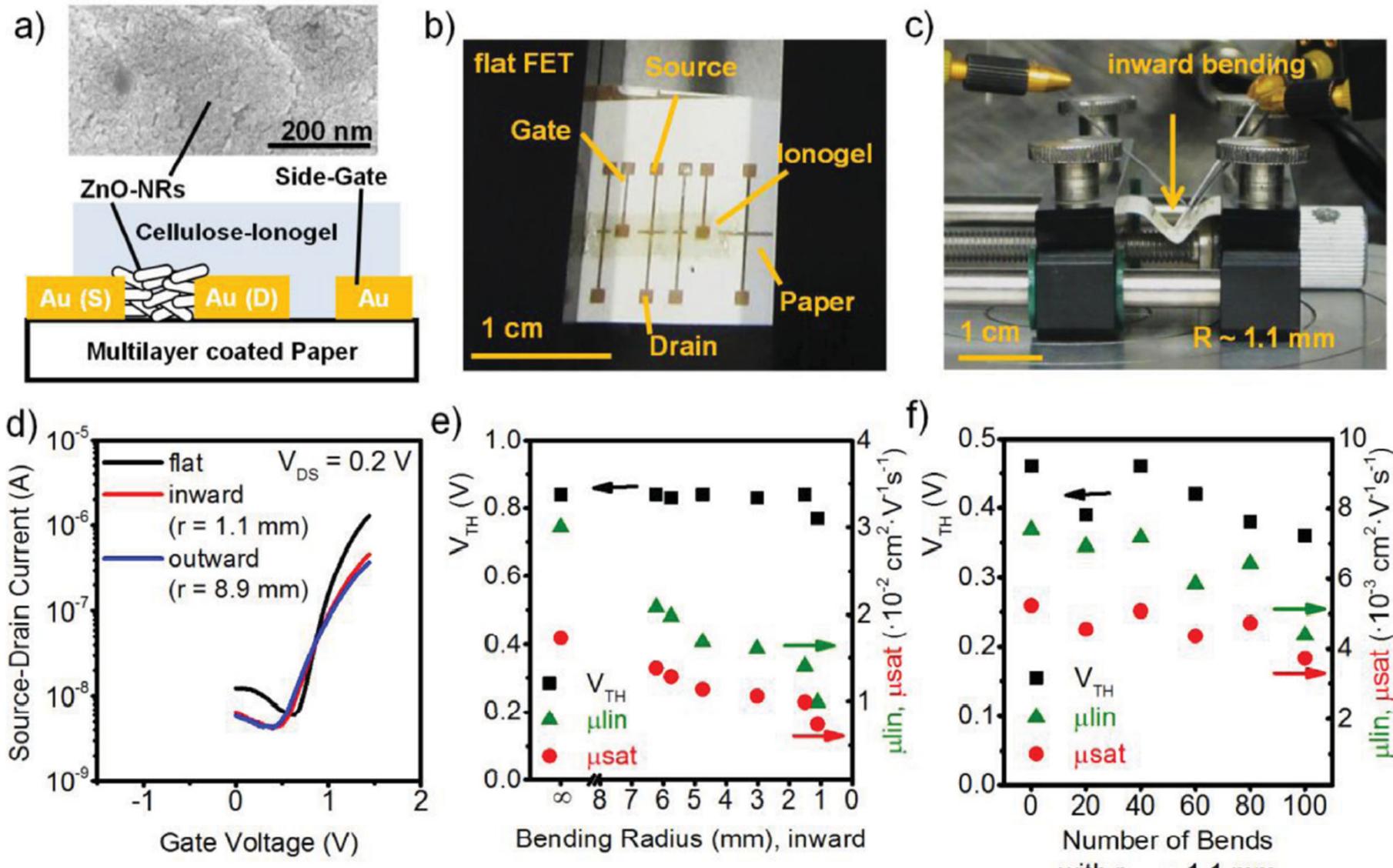
- *Totally novel approach*
 - *New production paradigms*
- *Critical is the control of the interfaces*

the search for quantitative stick testing



Schematic drawing of the RenaStick dipstick showing advantages and disadvantages of point-of-care testing in the setting of acute kidney injury. www.nature.com 2014

printed circuits on paper



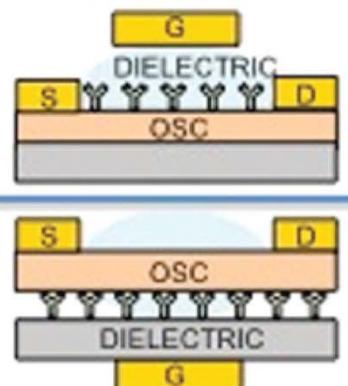
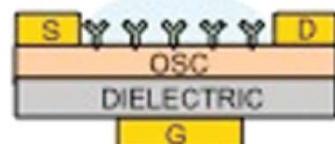
Thiemann, S. et al. "Cellulose-Based Ionogels for Paper Electronics," Adv. Fun. Mater. 2014, 24, 625–634.

TUTORIAL REVIEW

Chemical Society Reviews

c3cs60127g

OFET bio-sensors



Organic field-effect transistor sensors: a tutorial review

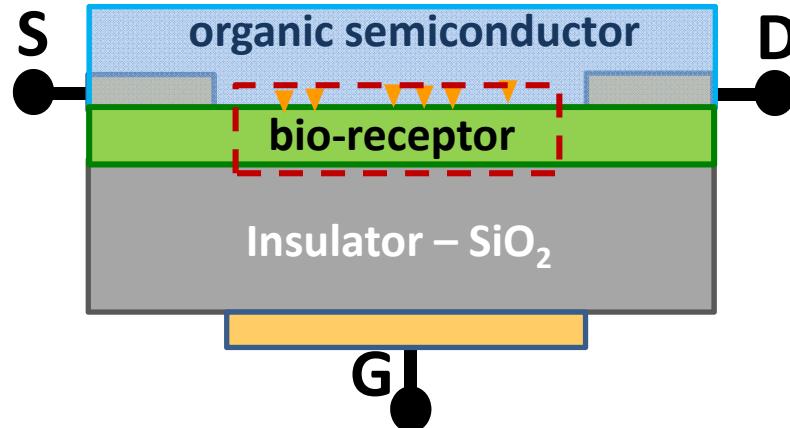
Luisa Torsi,* Maria Magliulo, Kyriaki Manoli and Gerardo Palazzo

Organic thin-film transistors embedding biological recognition elements are successfully employed as ultrasensitive, low-cost, label-free biosensors in several analytical fields.

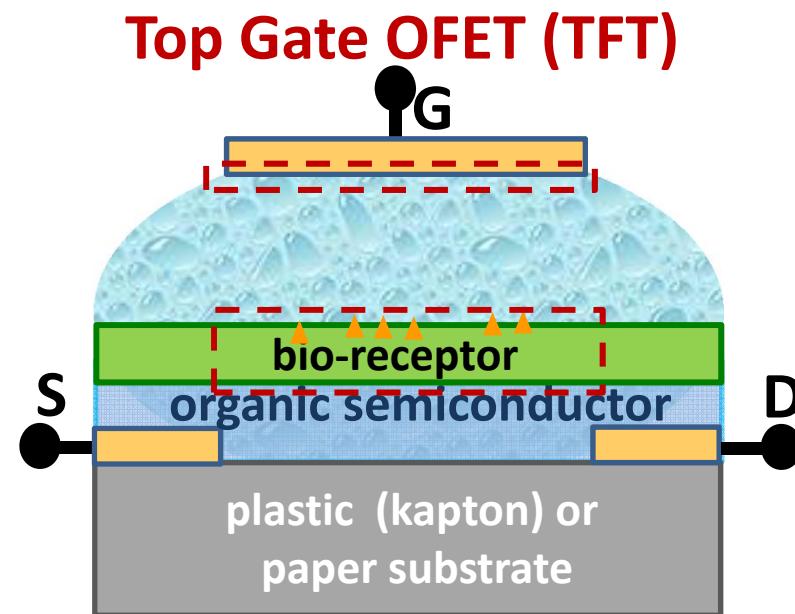
L. Torsi et al. Chem. Soc. Rev., 2013, 42 (22), 8612 - 8628

Luisa Torsi - Università degli Studi di Bari “Aldo Moro” (Italy)

impact of a binding event on electronic properties



Bottom Gate OFET (TFT)



$$\sqrt{I_{DS}} = \sqrt{\frac{W}{2L} \mu_{FET} C_i \cdot (V_G - V_T)}$$

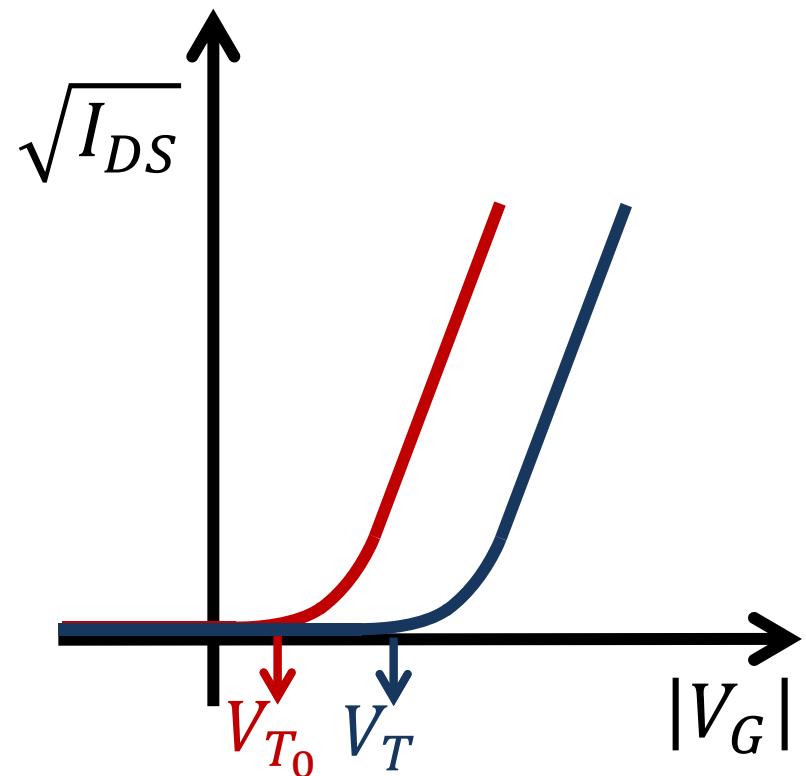
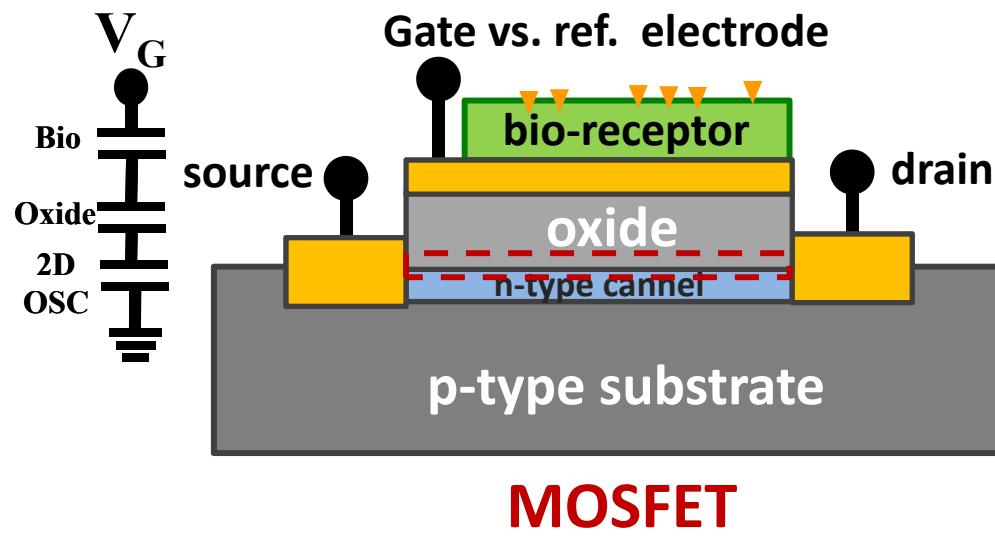
- impacts on OSC or gate metal electrochemical potential → V_T changes*
 - impacts on the OSC transport properties → μ_{FET} changes*
 - Impacts on the gating system capacitance → C_i changes*

Ion Selective FET (ISFET) like bio-sensor

$$\sqrt{I_{DS}} = \sqrt{\frac{W}{2L} \mu_{FET} C_i \cdot (V_G - V_T)}$$

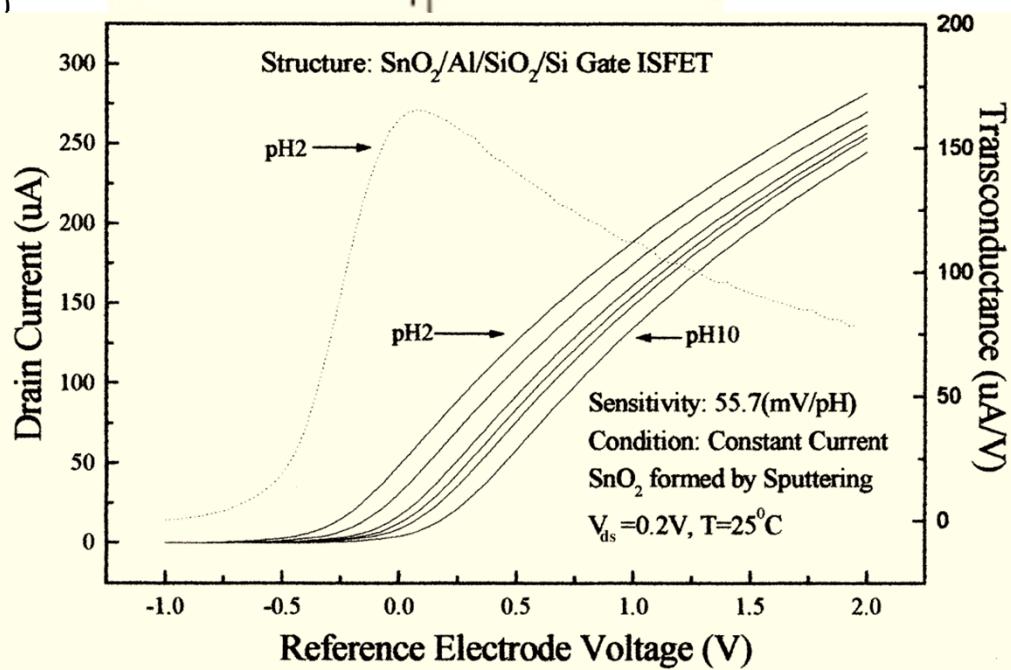
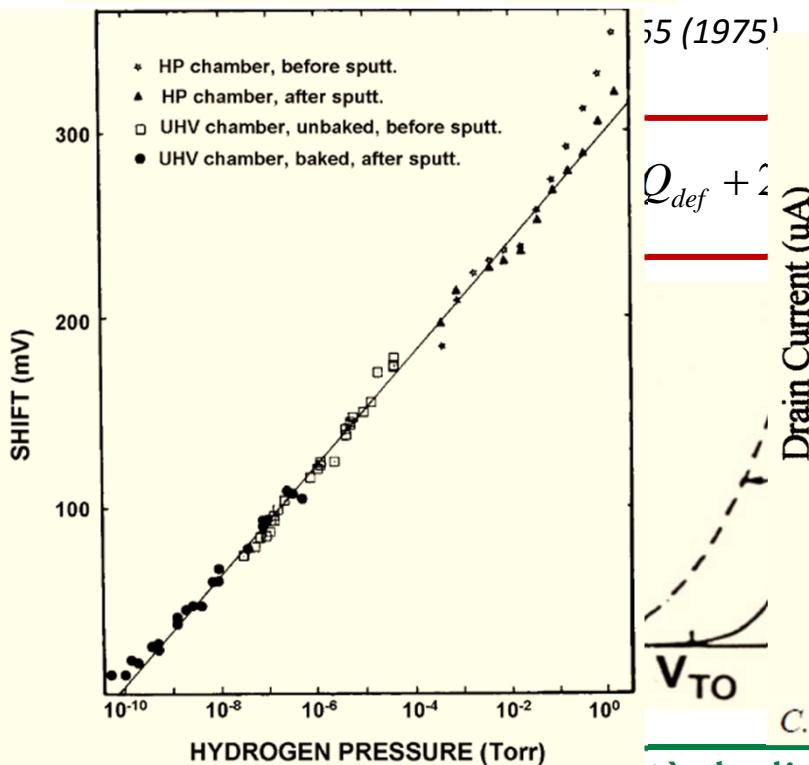
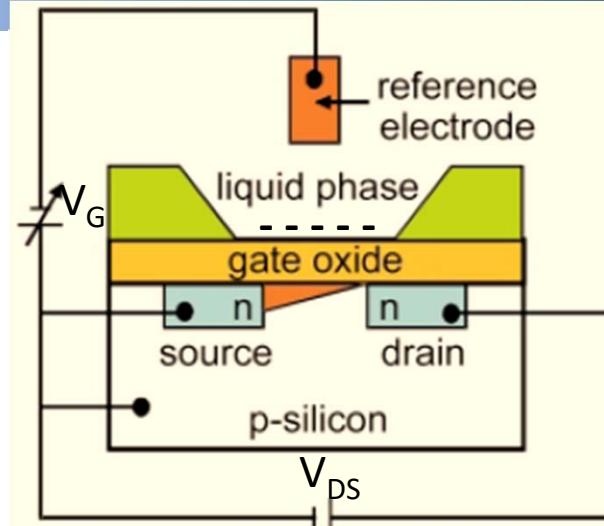
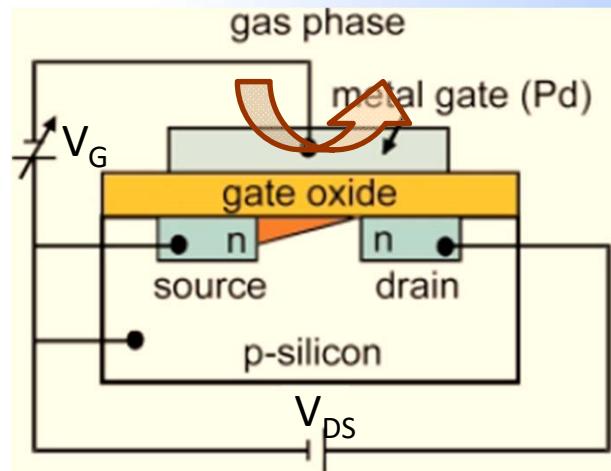
$$\mu_{FET} = \text{cost}$$

$$C_i = \text{cost}$$



$$\frac{\Delta I}{I} = \frac{2 \Delta V_T}{(V_G - V_T)}$$

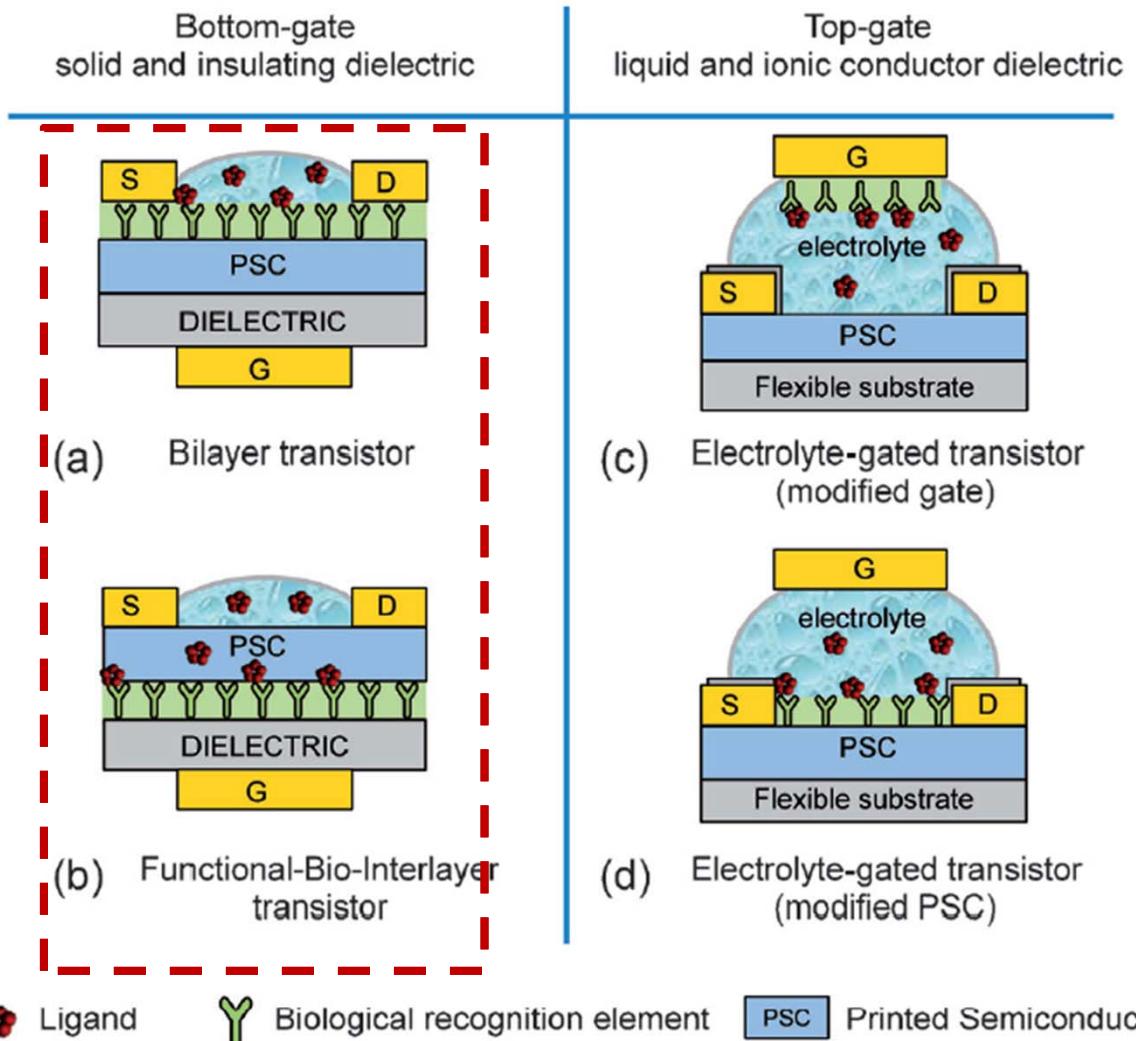
GAS & Ion-Selective FET (ISFET)



C.-L. Wu et al. / Materials Chemistry and Physics 63 (2000) 153–156

electronic OFET bio-sensors

FBI-OFET



L. Torsi et al. *Angew. Chem. Int. Ed.* **2015**, *54*, 12562–12576

April 24, 2012 | vol. 109 | no. 17 | pp. 6429–6434

PNAS

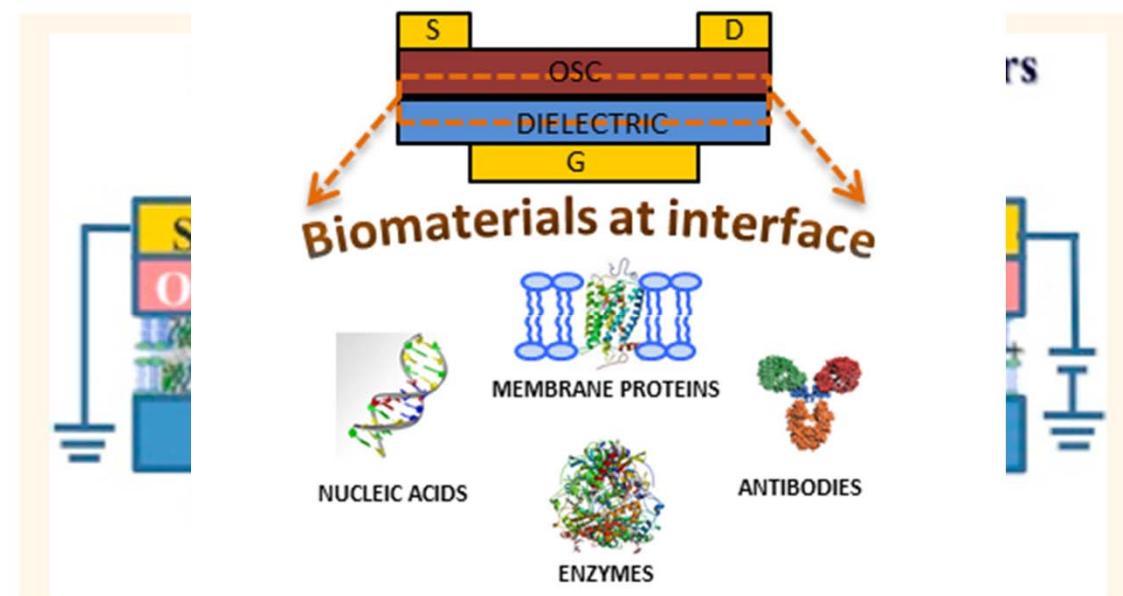
Proceedings of the National Academy of Sciences of the United States of America

www.pnas.org

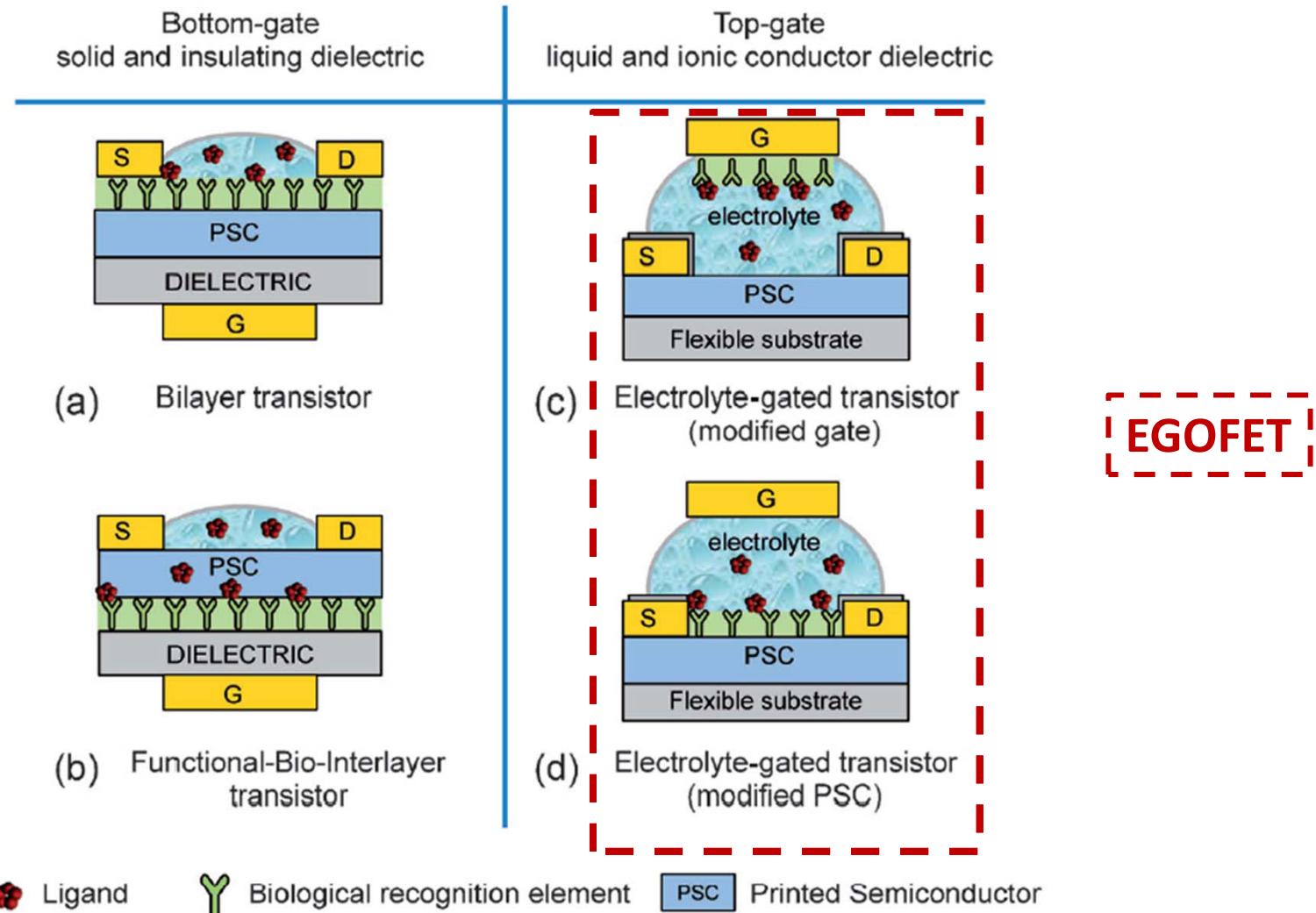
Interfacial electronic effects in functional biolayers integrated into organic field-effect transistors

Tailoring Functional Interlayers in Organic Field-Effect Transistor Biosensors

Maria Magliulo, Kyriaki Manoli, Eleonora Macchia, Gerardo Palazzo, and Luisa Torsi*

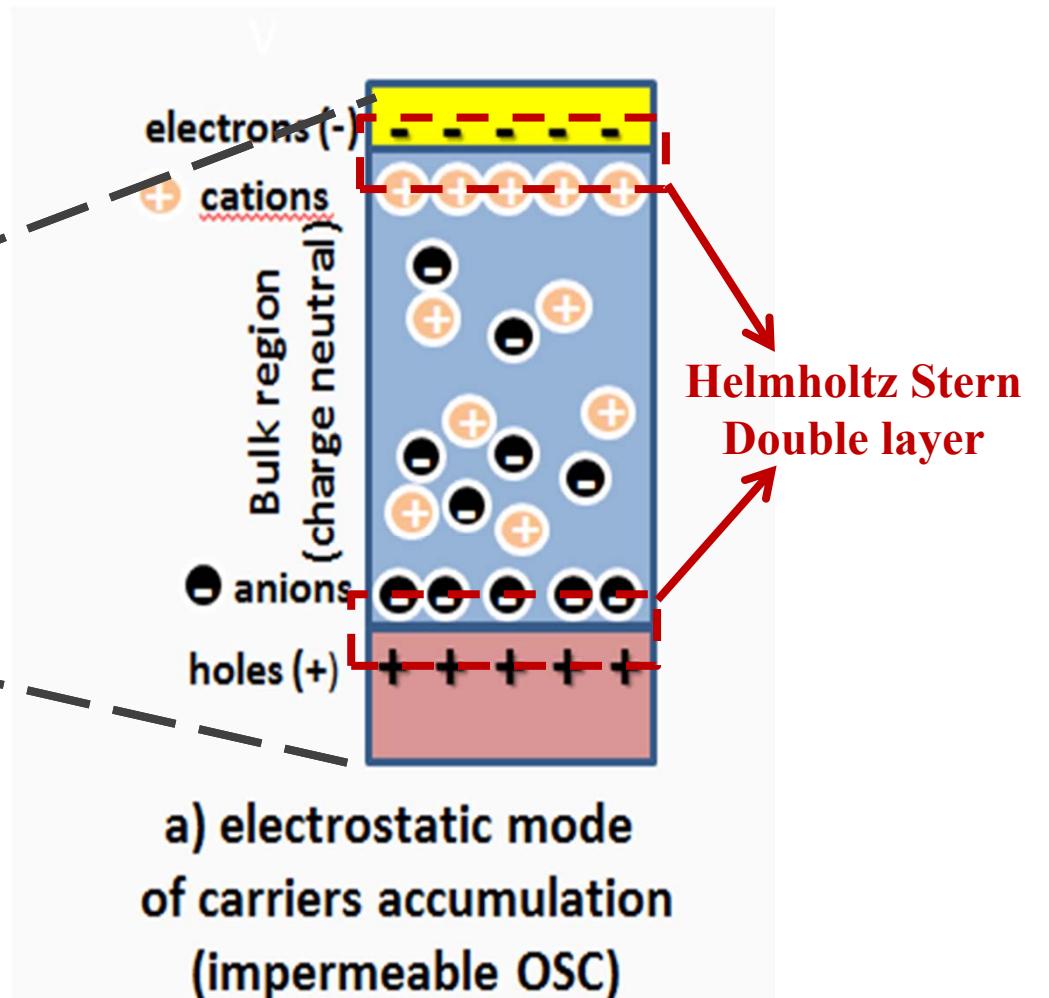
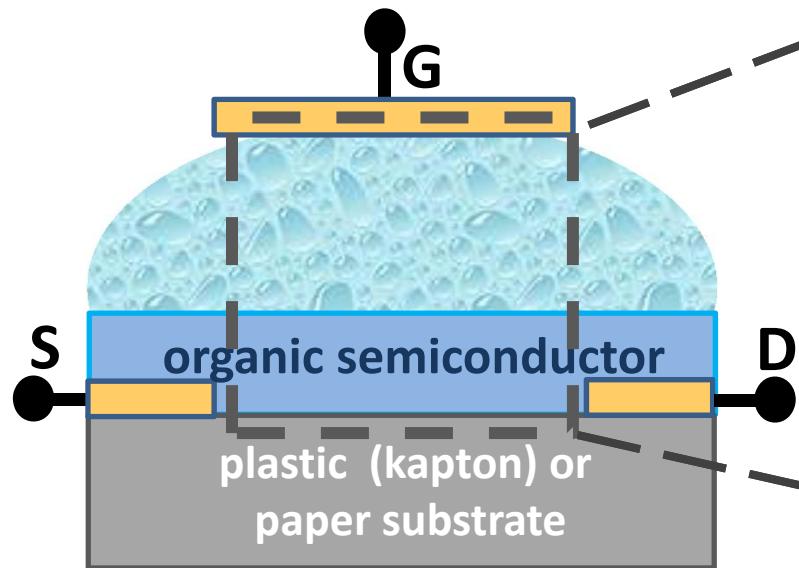


electronic OFET bio-sensors



L. Torsi et al. *Angew. Chem. Int. Ed.* **2015**, *54*, 12562–12576

how Electrolyte Gated OFETs work



water self-ionization

H. Klauk, *Organic electronics II: More materials and applications*; Wiley-VCH
S. H. Kim, K. Hong, W. Xie, K. H. Lee, S. Zhang, T. P. Lodge, C. D. Frisbie,
Adv. Mater. 2013, 25, 1822-1846;

Polyelectrolytes in EGOFET

ACS APPLIED MATERIALS
& INTERFACES

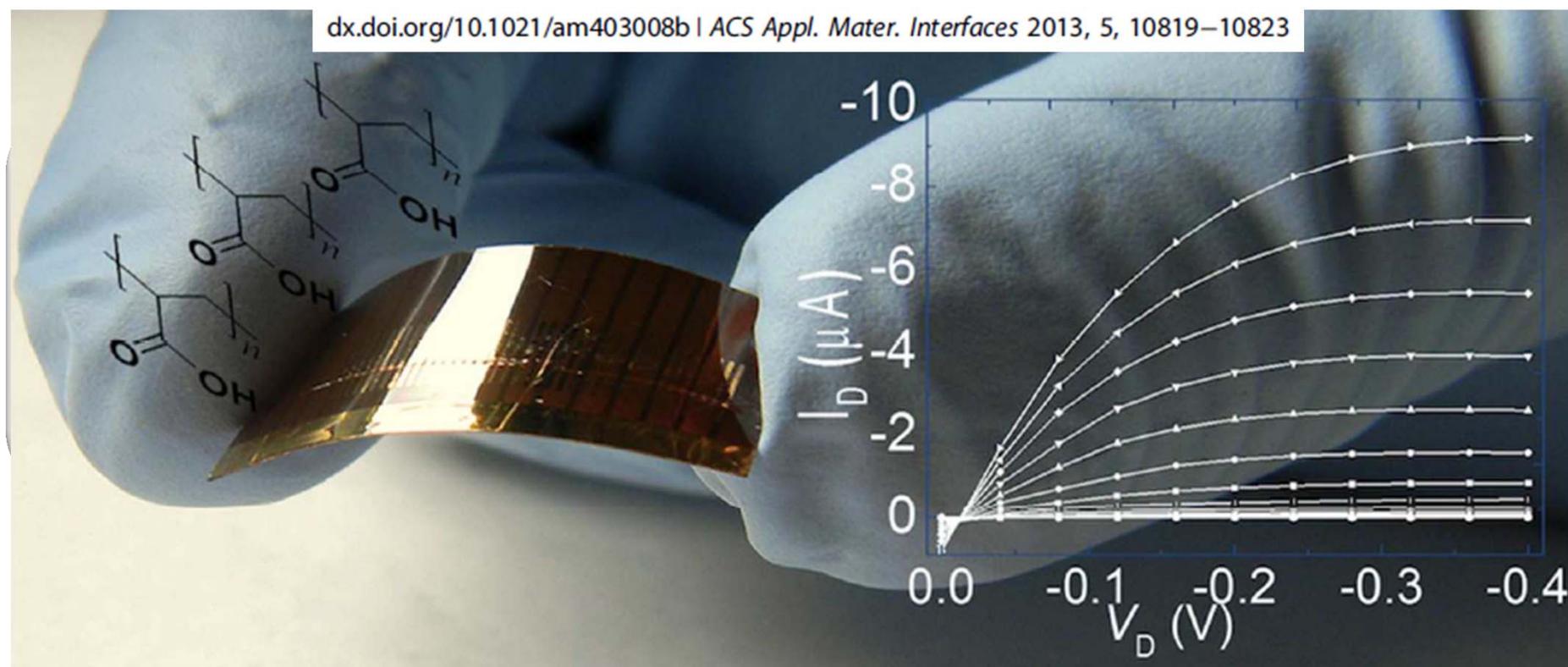
Research Article

www.acsami.org

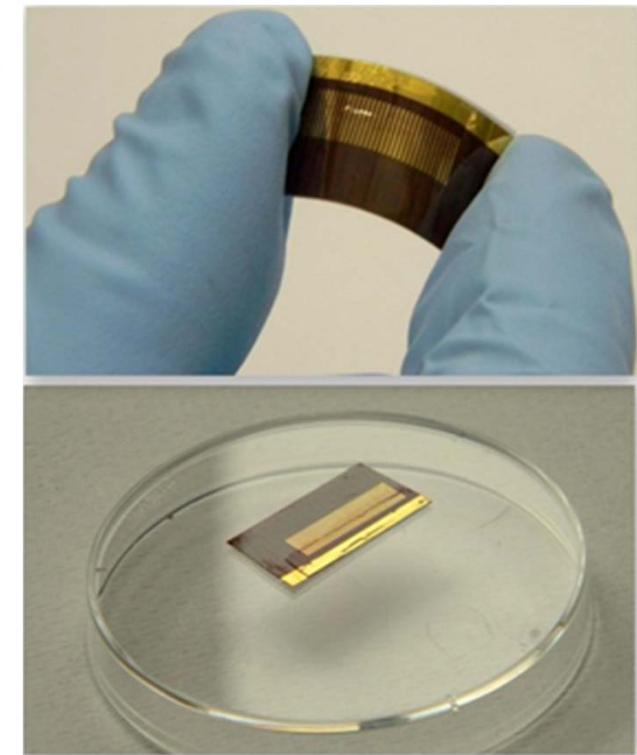
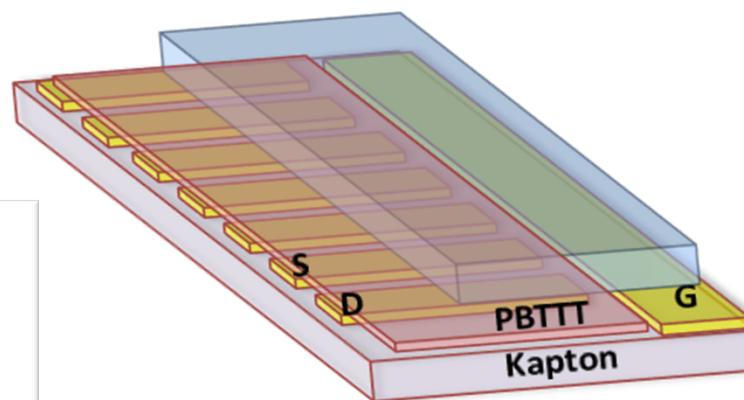
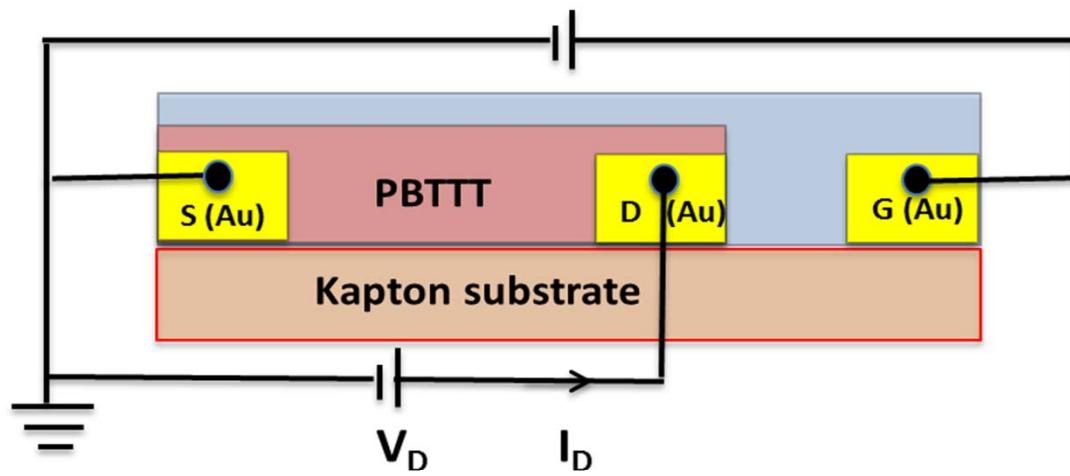
Plain Poly(acrylic acid) Gated Organic Field-Effect Transistors on a Flexible Substrate

Liviu M. Dumitru, Kyriaki Manoli, Maria Maglialo, Luigia Sabbatini, Gerardo Palazzo, and Luisa Torsi*

Department of Chemistry, “Aldo Moro” University, Via Orabona 4, Bari 70126, Italy



EGOFET - architectures



Devices channel length $L = 200 \mu\text{m}$
channel width $W = 4000 \mu\text{m}$
Substrates: polyimide (Kapton®)

New polyelectrolyte as gating material in OFETs

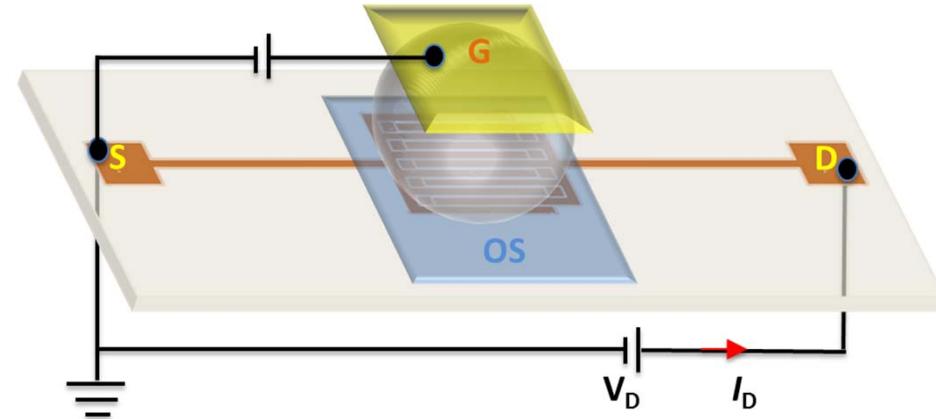
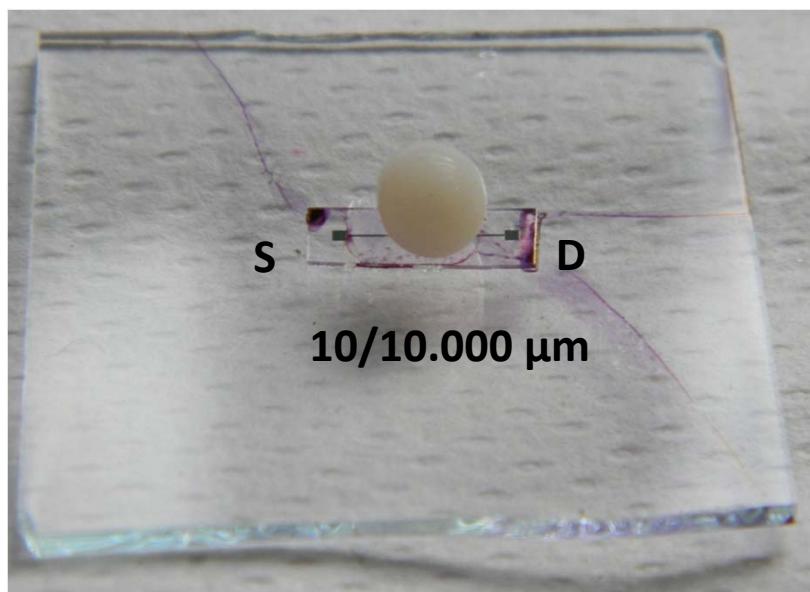
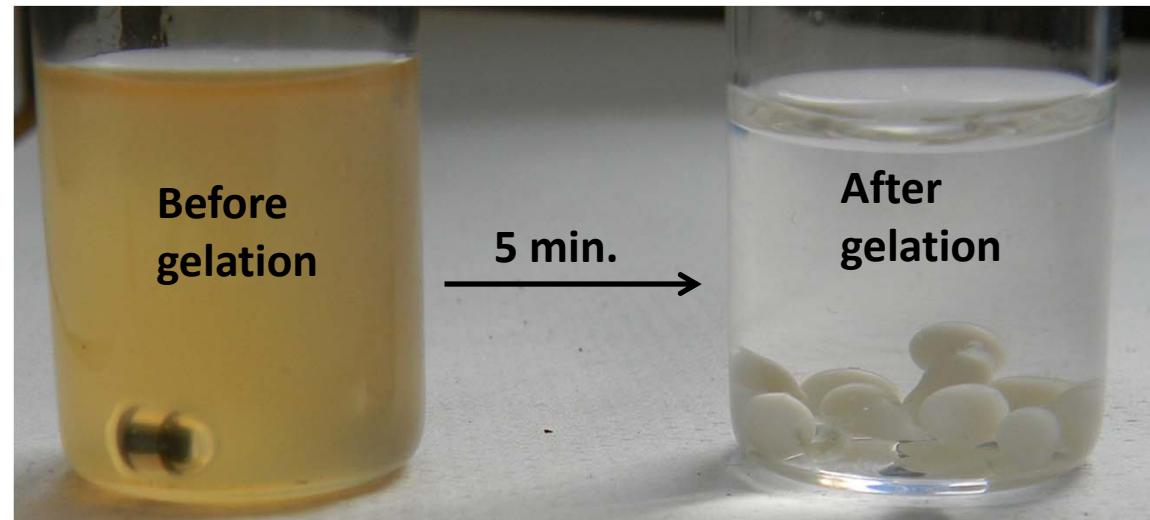
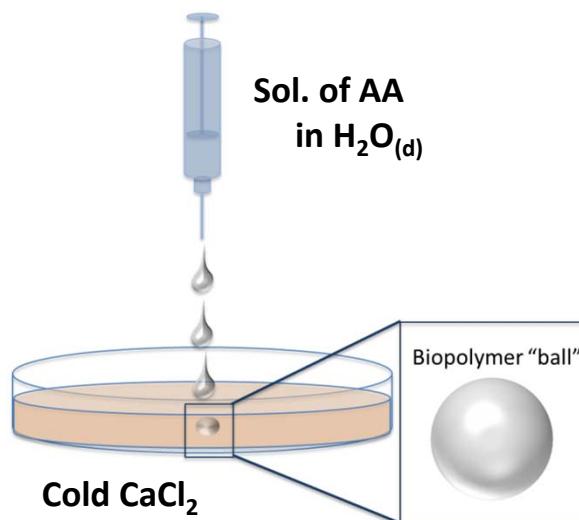


Calcium alginate fruit (blueberry) "caviar"

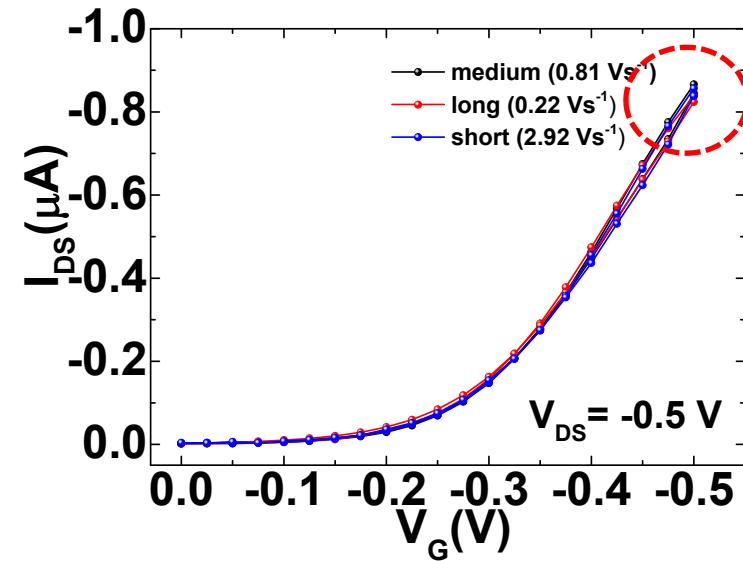
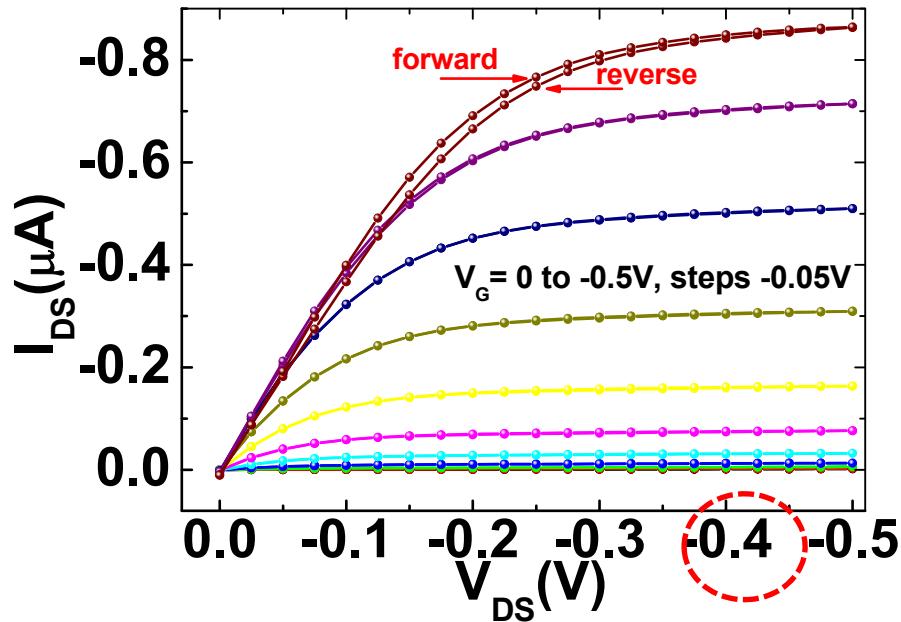


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Alginic capsules



Electrical performance



<i>Capsule based OFET</i>	<i>Average</i> $(n=7)^*$	<i>Best</i>
$\mu \text{ (cm}^2 \text{ V}^{-1} \text{ s}^{-1}\text{)}$	$(1.7 \times 10^{-2} \pm 4 \times 10^{-3})$	2.3×10^{-2}
$V_T \text{ (V)}$	(-0.029 ± 0.019)	-0.004
<i>on/off</i>	(178 ± 158)	438

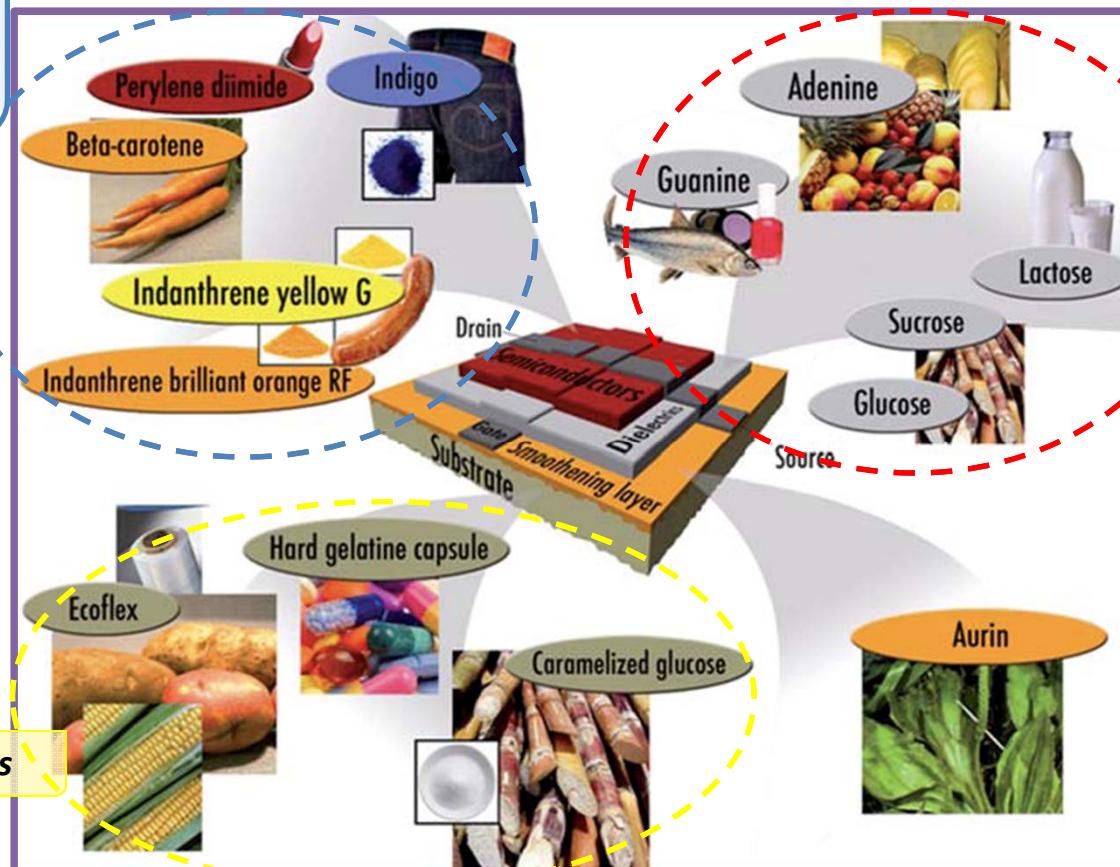
Green Electronics

Natural materials
or materials inspired by nature
in organic field-effect transistors

β -carotene and **indigo**
are natural
p- and n-type
organic semiconductors

hard gelatine
produced from collagen,
or **caramelized glucose**

exotic substrate materials



sugar
molecules
or
nucleobases

natural dielectrics
with **good
insulating properties**

Printing pigments



Materials
Views

www.MaterialsViews.com

**ADVANCED
MATERIALS**

www.advmat.de

Hydrogen-Bonded Semiconducting Pigments for Air-Stable Field-Effect Transistors

Eric Daniel Głowacki,* Mihai Irimia-Vladu, Martin Kaltenbrunner, Jacek Gąsiorowski, Matthew S. White, Uwe Monkowius, Giuseppe Romanazzi, Gian Paolo Suranna, Piero Mastorilli, Tsuyoshi Sekitani, Siegfried Bauer, Takao Someya, Luisa Torsi, and Niyazi Serdar Sariciftci

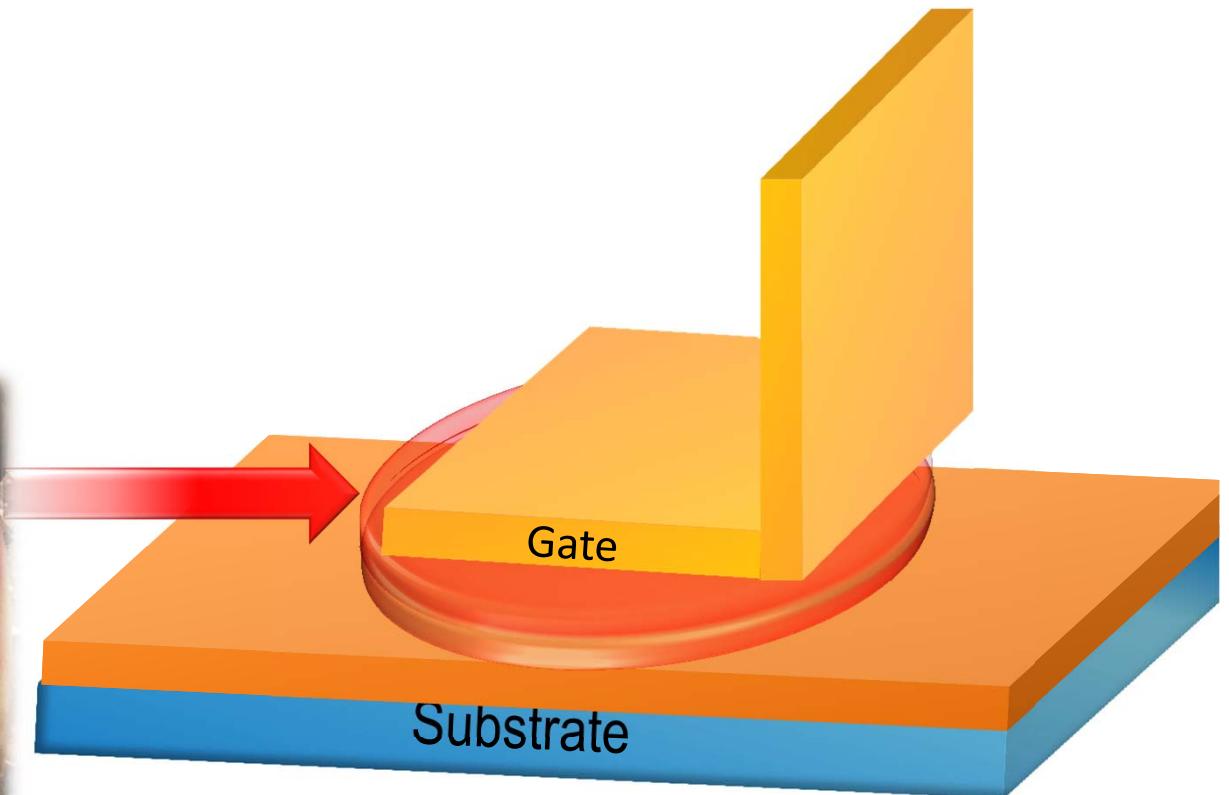


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From kitchen to lab: Curiosity driven research

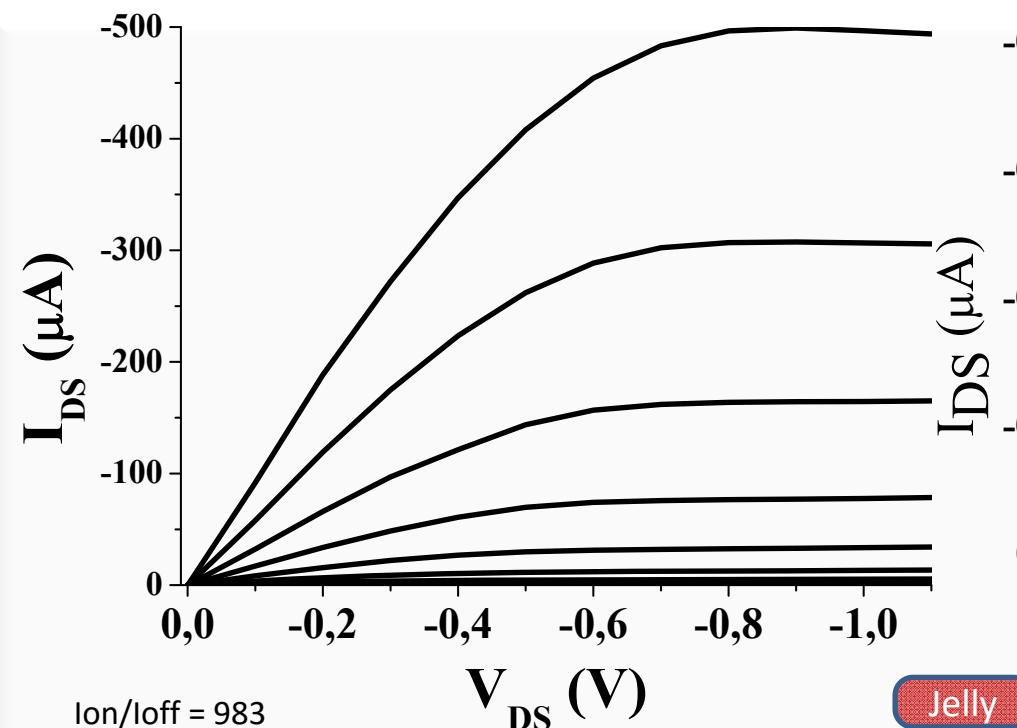


M. Y. Mulla

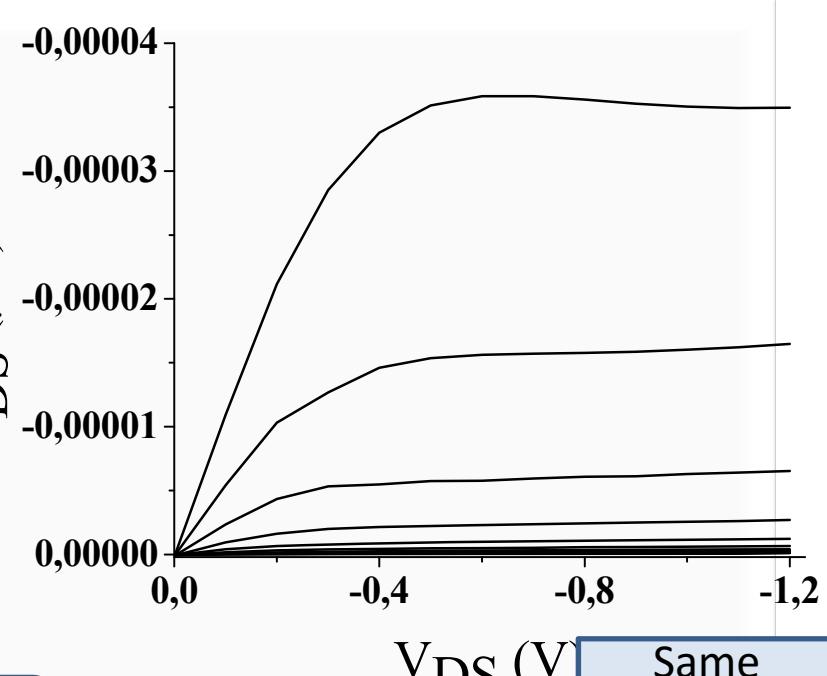




edible Gel di-electric

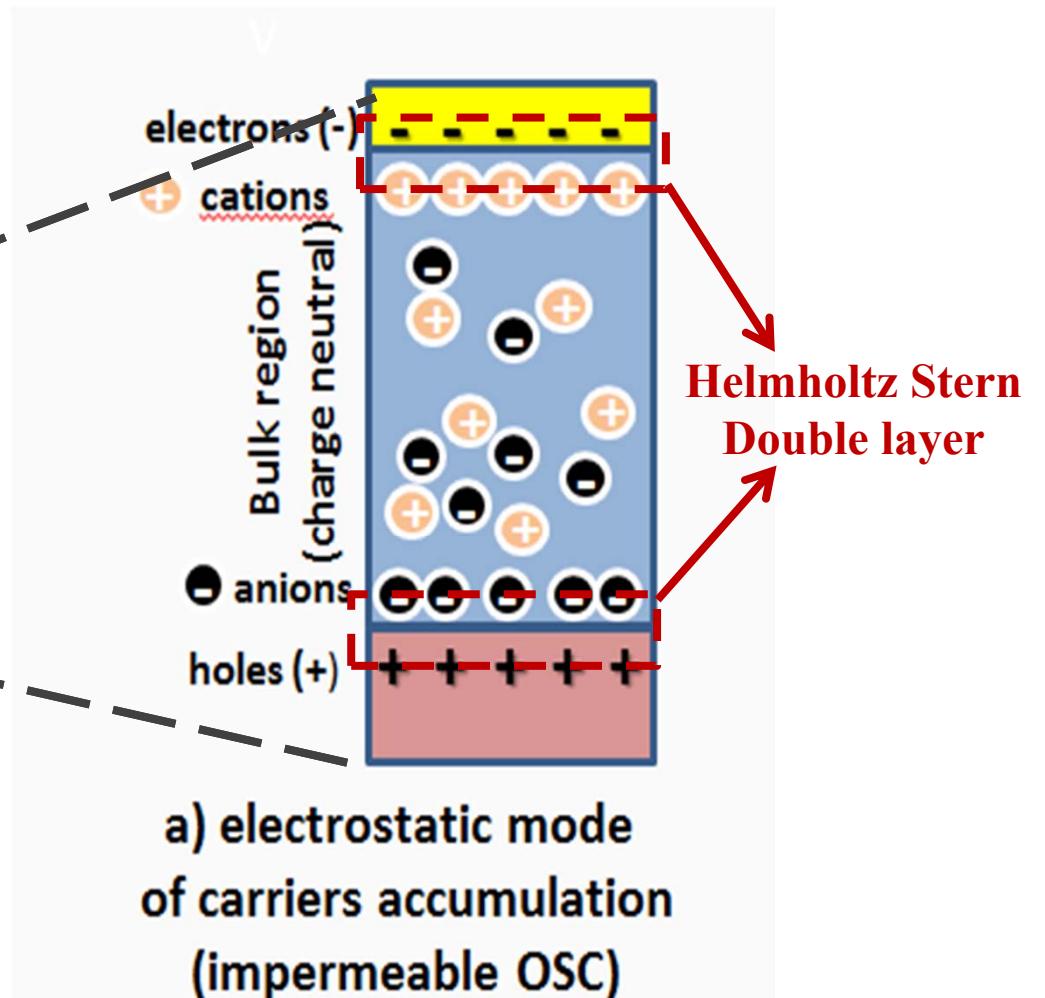
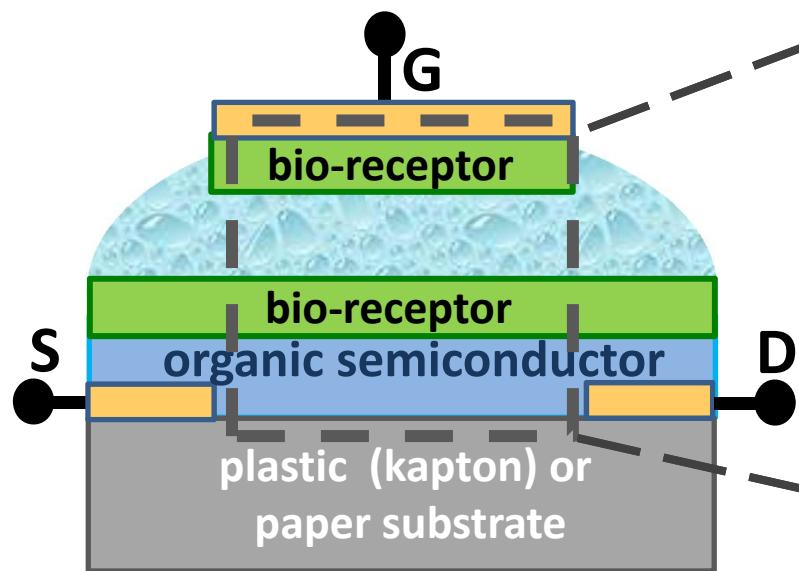


$I_{on}/I_{off} = 983$
 $\mu [\text{cm}^2/\text{V.s}] = 5.6 \text{ E-1}$
 $V_t [\text{V}] = -0.53$
 Channel L/W: 10/10000
 C = 5 (taken as approximate value
 because for ion gels literature values are
 from 5 to 10)



$I_{on}/I_{off} = 302$
 $\mu [\text{cm}^2/\text{V.s}] = 5.7 \text{ E-2}$
 $V_t [\text{V}] = -0.74$
 Channel L/W: 5/10000

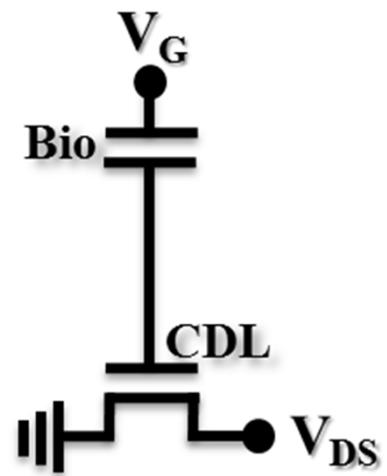
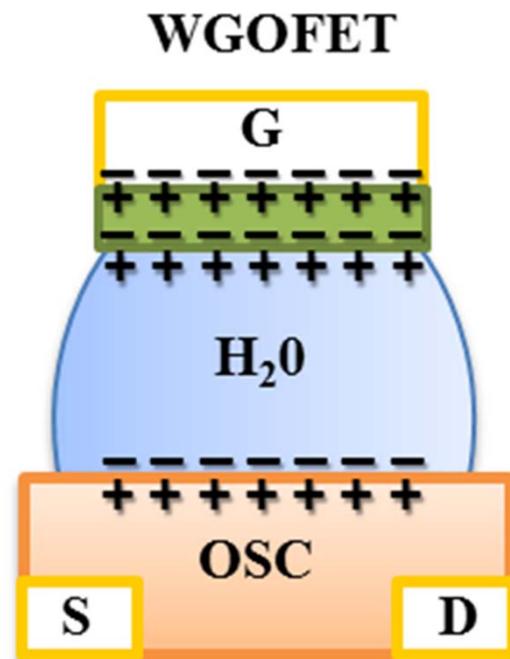
how EGOFETs work



water self-ionization

H. Klauk, *Organic electronics II: More materials and applications*; Wiley-VCH
S. H. Kim, K. Hong, W. Xie, K. H. Lee, S. Zhang, T. P. Lodge, C. D. Frisbie,
Adv. Mater. 2013, 25, 1822-1846;

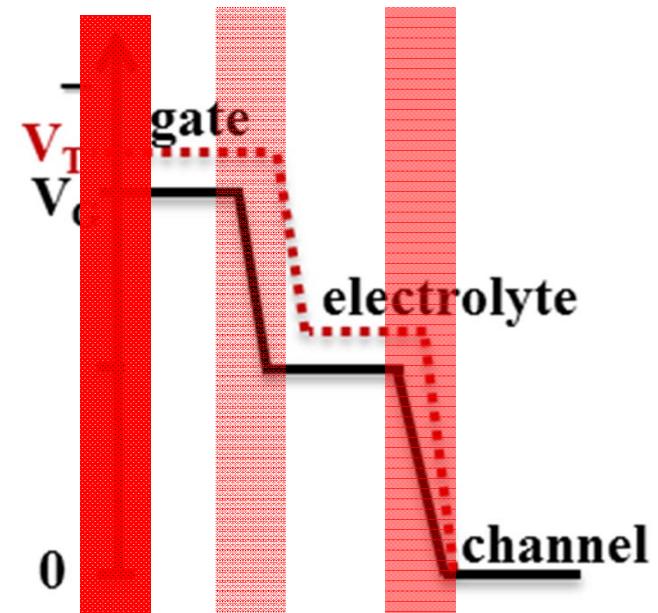
the capacity modulated device



$$C_{CDL} \sim 10-10^2 \mu\text{F}/\text{cm}^2$$

$$C_{BIO} \sim 10^{-1} \mu\text{F}/\text{cm}^2$$

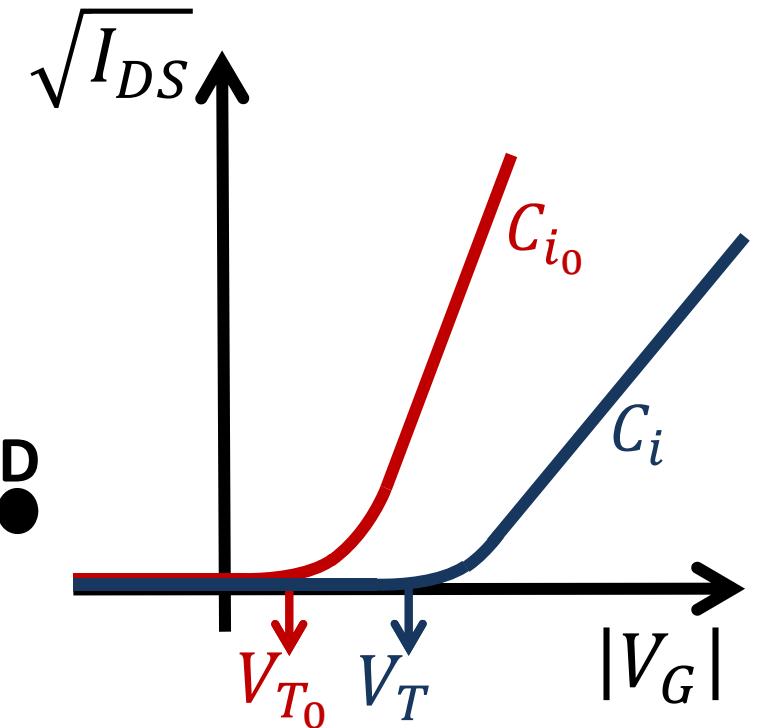
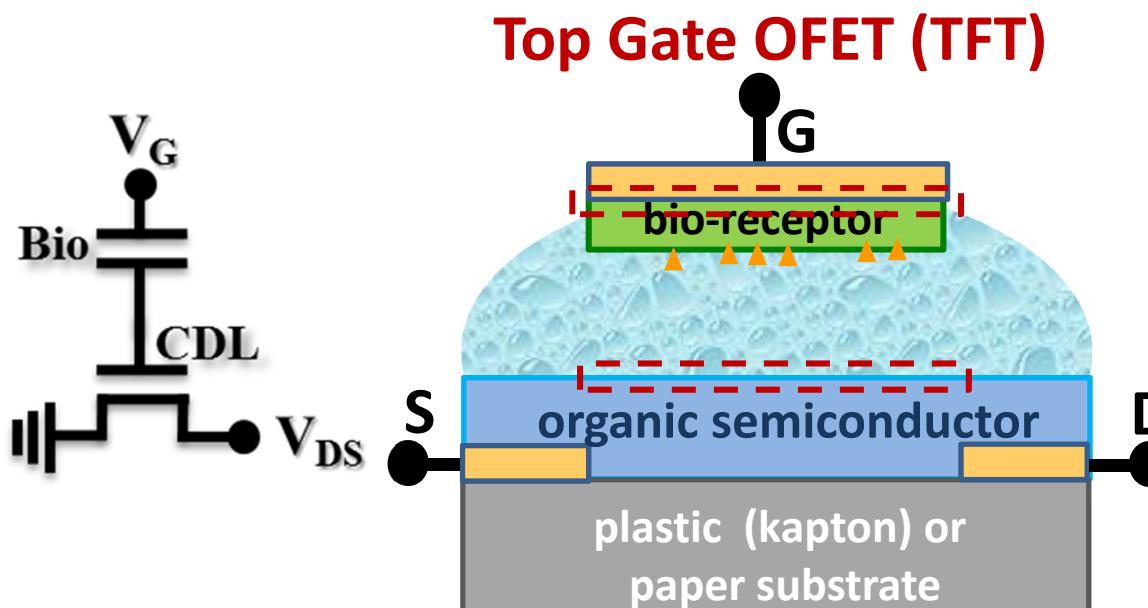
$$C_{BIO} \ll C_{CDL}$$



electrolyte gated OFET (EGOFET) sensor

$$\sqrt{I_{DS}} = \sqrt{\frac{W}{2L} \mu_{FET} C_i \cdot (V_G - V_T)}$$

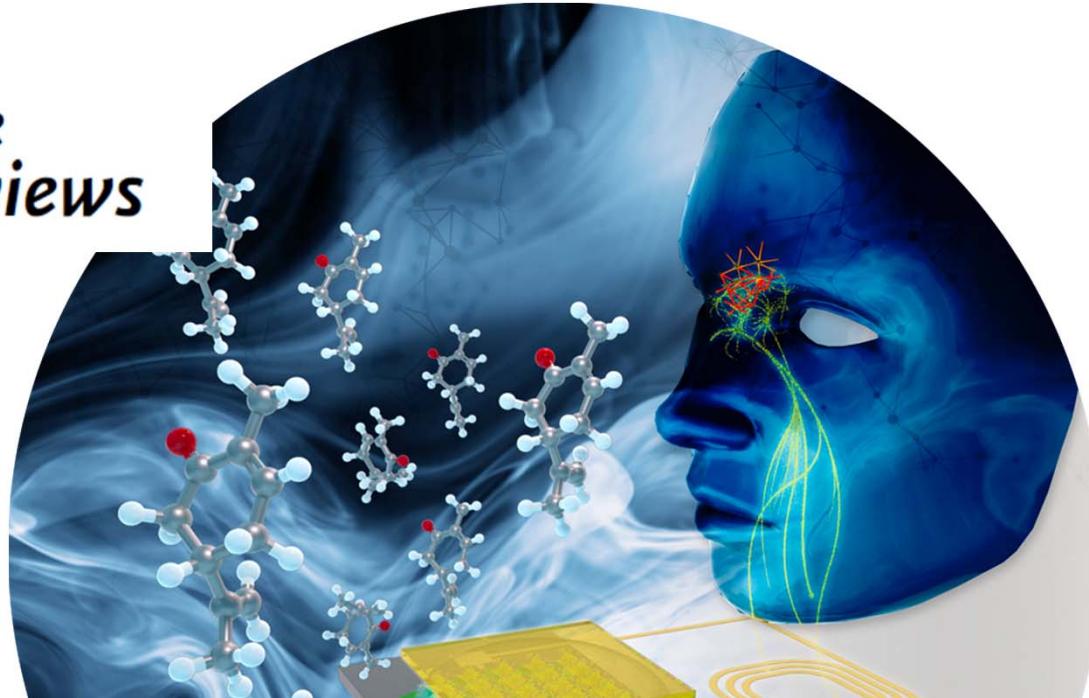
$\mu_{FET} = \text{cost}$



$$\frac{\Delta I}{I} = \frac{\Delta C_i}{C_i} - \frac{2 \Delta V_T}{(V_G - V_T)}$$

water gated OFET sensors - review

*Angewandte
Reviews*



charged species → stronger long-range coulomb interactions
(10-100 kJ/mol) → electrochemical potential → ISFET

neutral species (or species carrying a dipole moment) → weaker short-range interactions such as the dipole-dipole or the dispersive ones
(2 kJ/mol) → chemical potential → capacity modulated FET

L. Torsi et al *Angew. Chem. Int. Ed.* 2015, 54, 12562 – 12576

Odorant Binding Proteins EGFOT sensor



ARTICLE

Received 1 Aug 2014 | Accepted 2 Dec 2014 | Published 16 Jan 2015

DOI: 10.1038/ncomms7010

OPEN

Capacitance-modulated transistor detects odorant binding protein chiral interactions

Mohammad Yusuf Mulla¹, Elena Tuccori², Maria Magliulo¹, Gianluca Lattanzi³, Gerardo Palazzo¹, Krishna Persaud² & Luisa Torsi¹

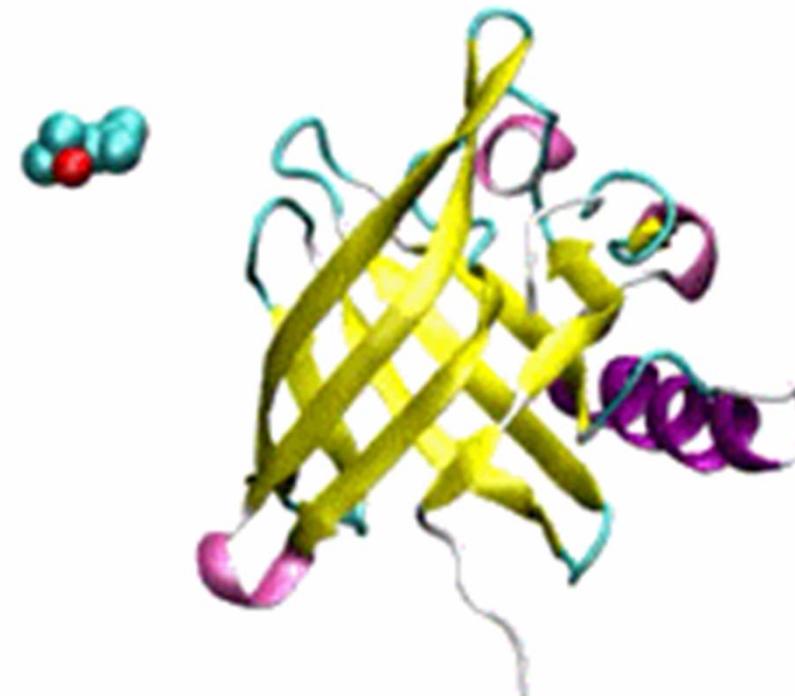
Mulla, M.Y. et al. *Nature Communications*, 2015, 6, 6010

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Odorant Binding Proteins

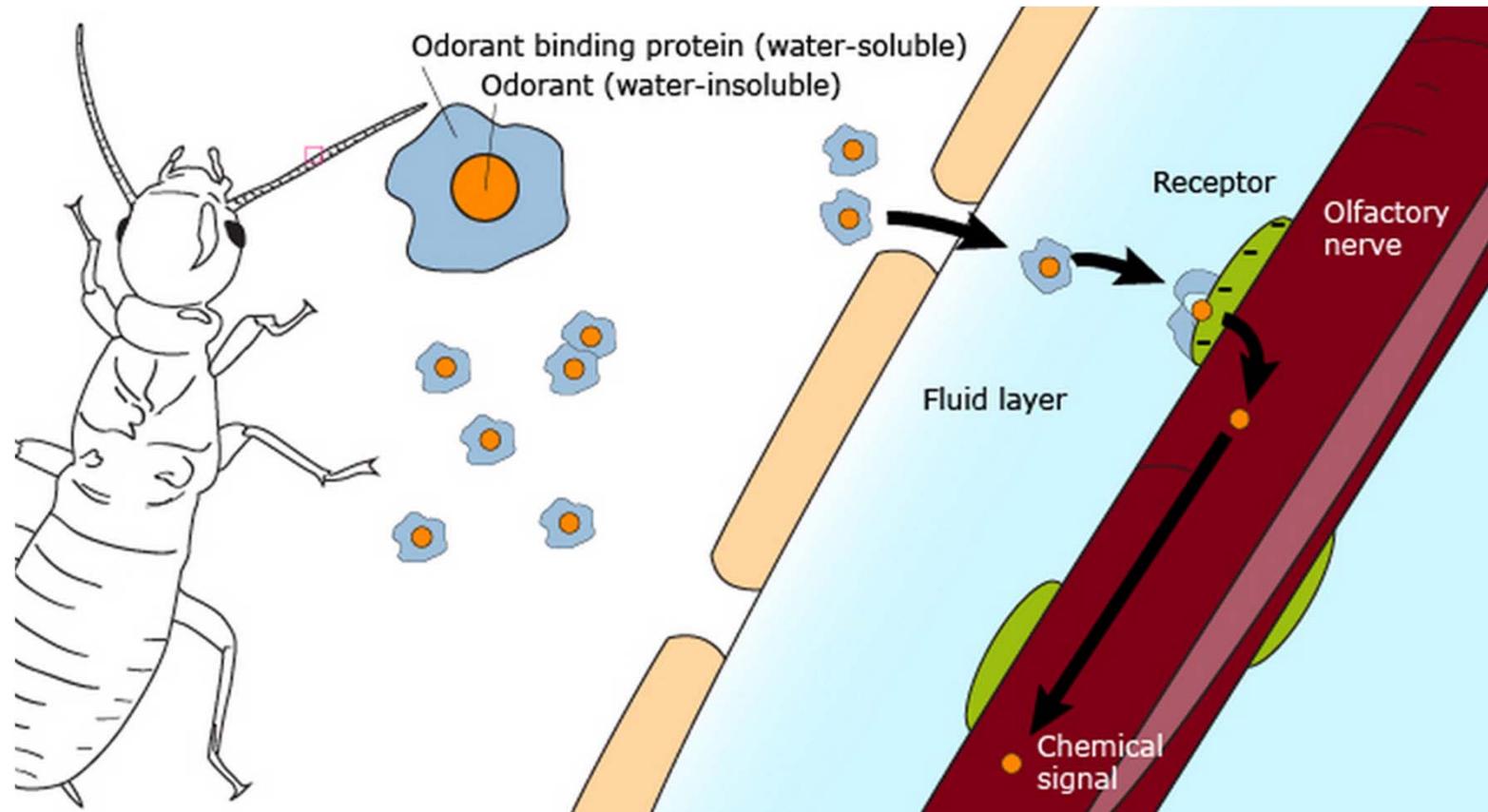


Krishna Persaud e Elena Tucconi
The University of Manchester,



pOBP is a monomer of 157 amino acid residues (molecular mass of *ca.* 19 kDa) with a height of 38.04 Å and a base of 25.70 Å x 26.40 Å.

Odorant Binding Proteins



Artist: Emily Harrington. Copyright: All rights reserved

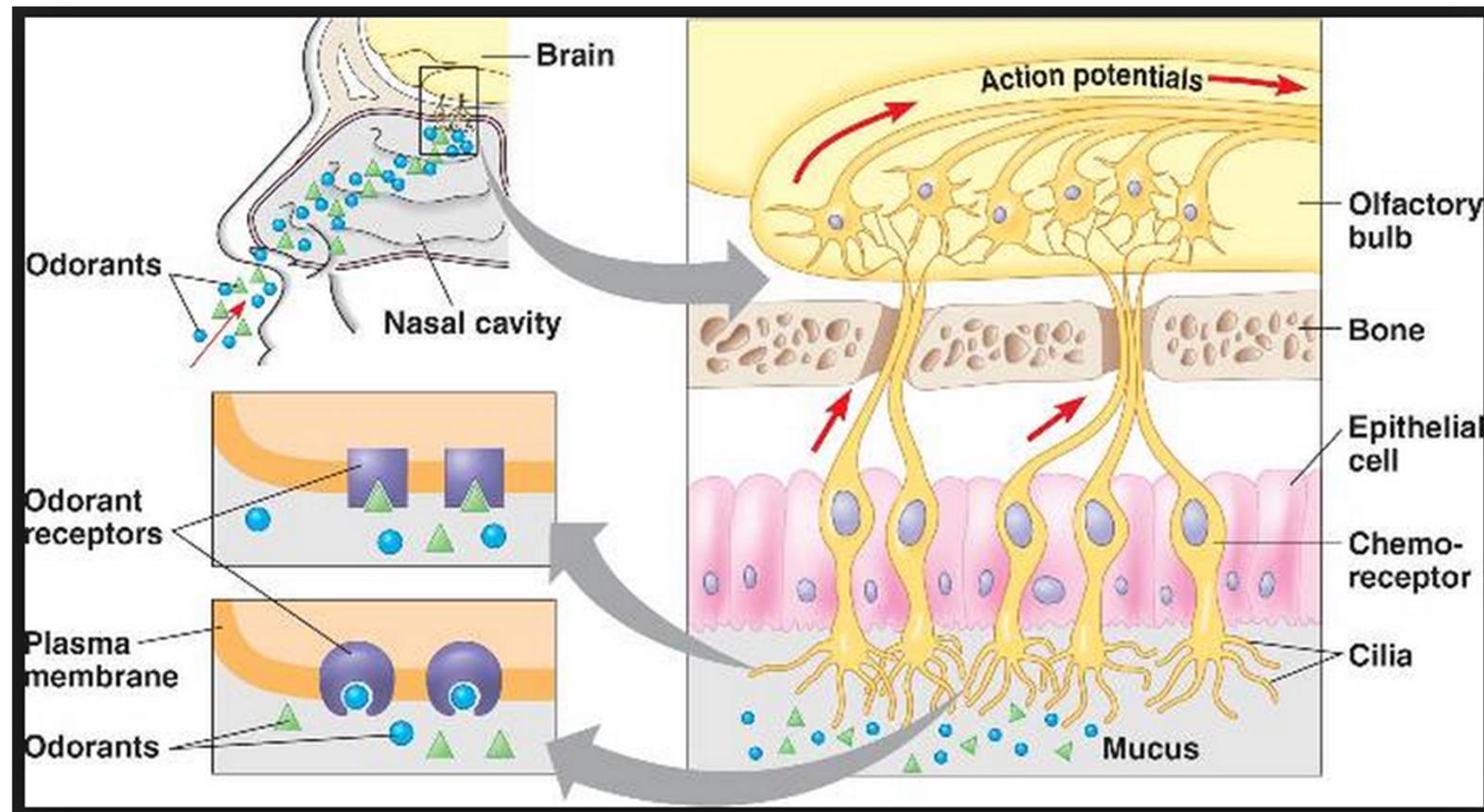
Shuttle odorant molecules

Odorant clearance mechanism

 **FLEXSmell**



vertebrate odorant system



 **FLEXSmell**

Luisa Torsi - Università degli Studi di Bari “Aldo Moro” (Italy)

why odorant binding proteins ?

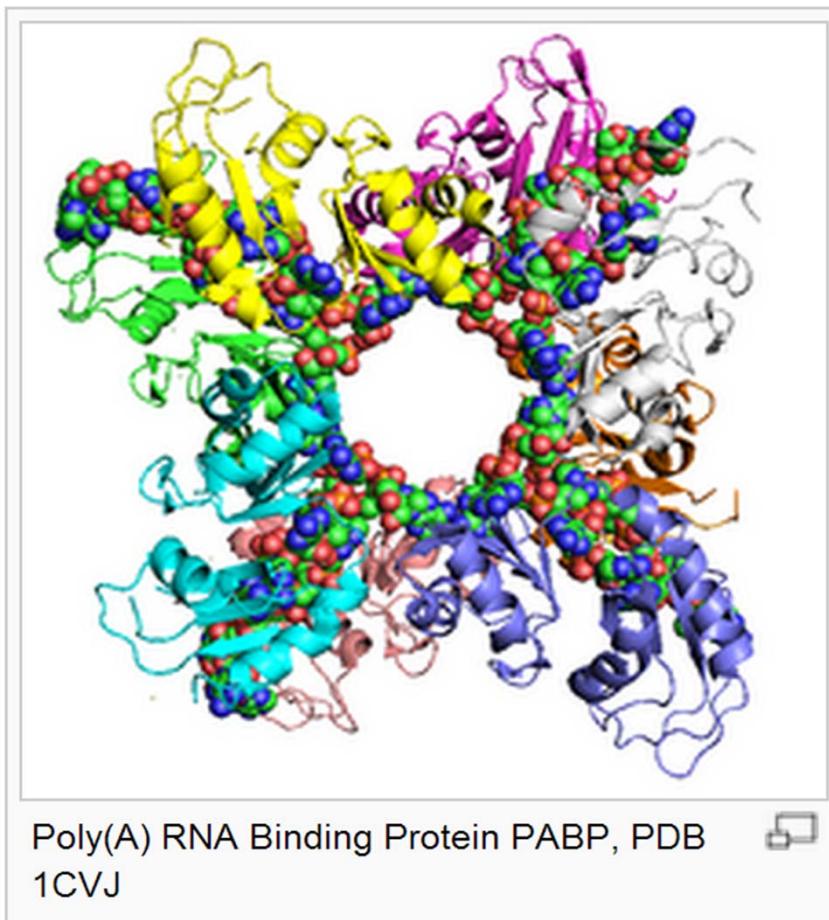
- OBP^s are present in high concentrations of mM range in mammalian nose and insects antennae
- Soluble proteins, can be expressed in bacterial systems at low-cost
- Highly stable – in ambient/hot conditions
 - Binds reversibly to odorants



pig Odorant Binding Proteins (pOBP)



Pig odorant binding proteins (pOBP)



The protein is characterized by a hydrophobic β -barrel cavity,

Differently from other OBPs such as the bovine one, pOBP β -barrel cavity is devoid of naturally occurring bound ligand

It bears a negative charge

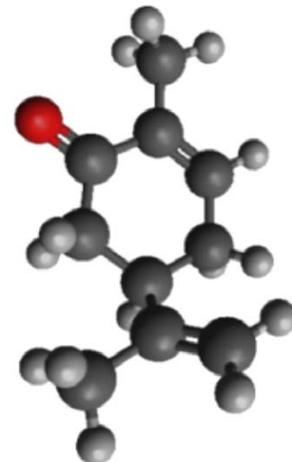
No study on chiral interactions; carvone enantiomers



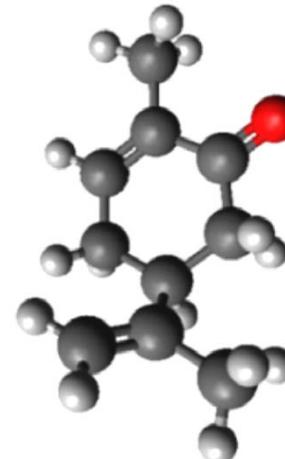
FLEXSmell

chiral ligand molecules

R(-)-Carvone



Caraway smell



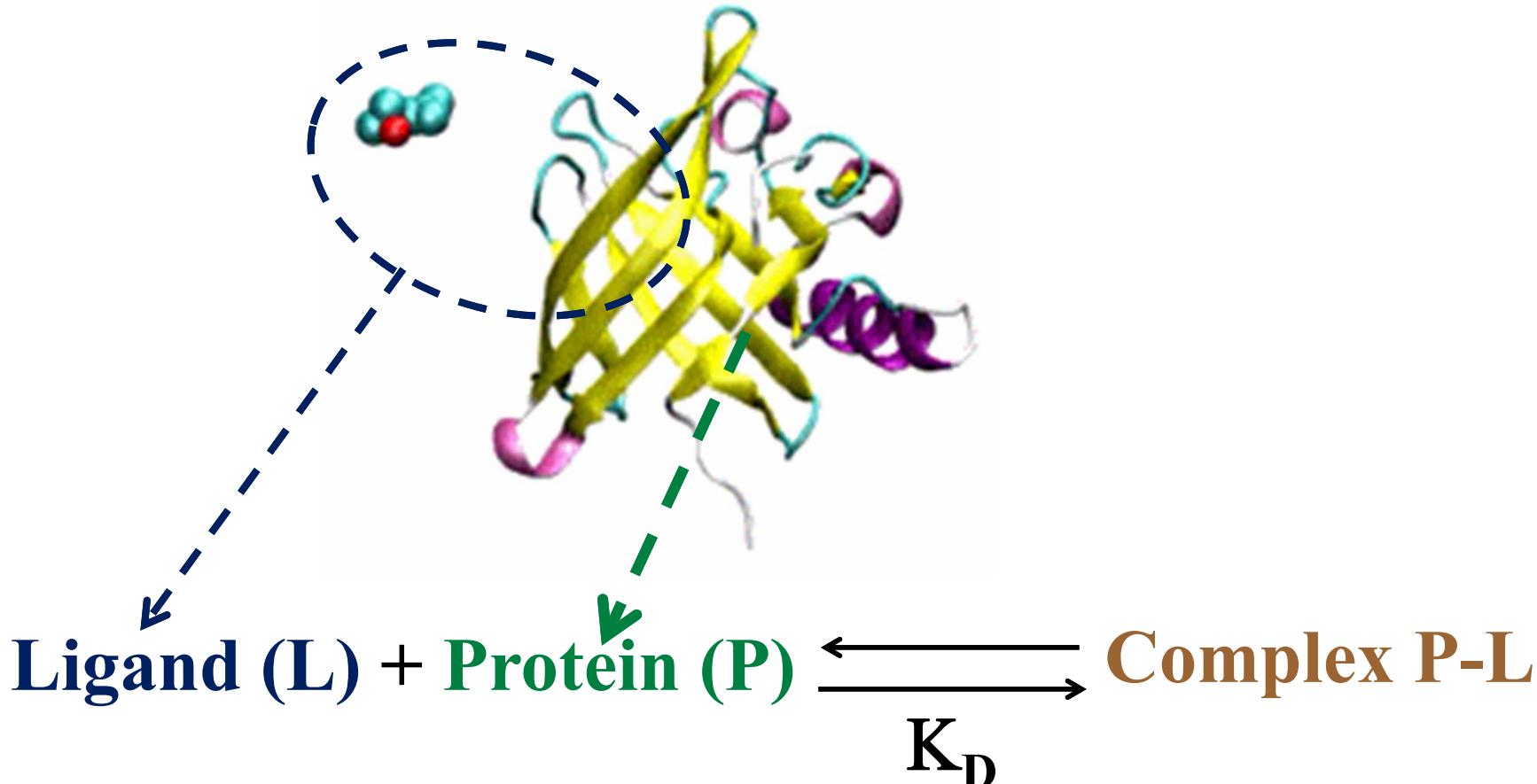
S(+)-Carvone

hydrophobic volatile, neutral small molecules are perceived as spearmint or caraway flavours with human threshold for detections of 30 and 420 nM

dipole moment of 3.2-3.6 D associated with the ketone group

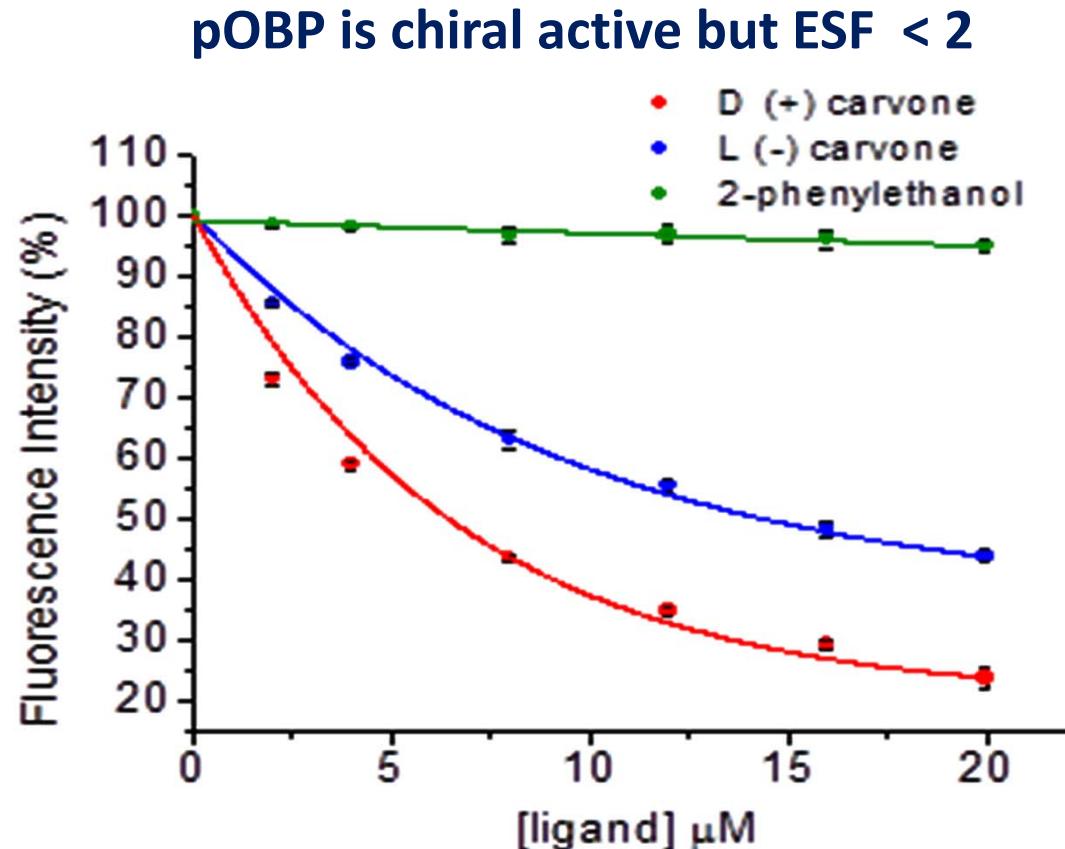
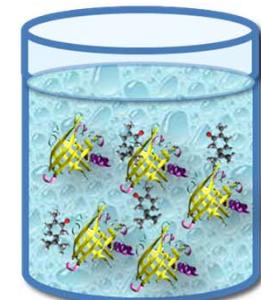
The binding process

 FlexSmell



$$K_D = [L] @ \text{half occupied protein sites}$$

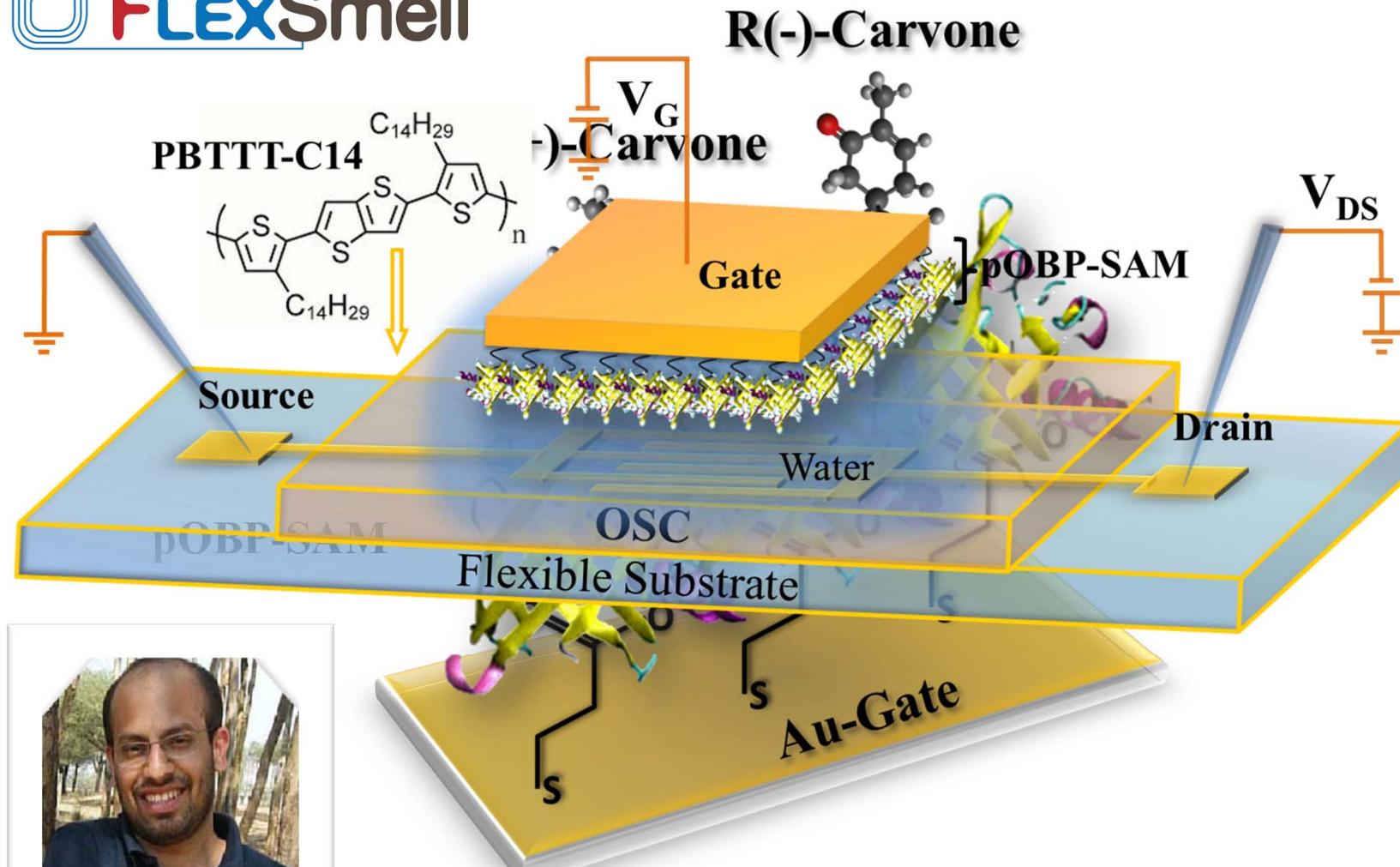
competitive fluorescent bidding assay



$$K_{\text{sol}}^{(+)} = 0.50 \pm 0.01 \mu\text{M} \text{ and } K_{\text{sol}}^{(-)} = 1.22 \pm 0.05 \mu\text{M}$$

2-phenylethanol is shown to binds very weakly to pOBPs (K_D ca. 40 mM)

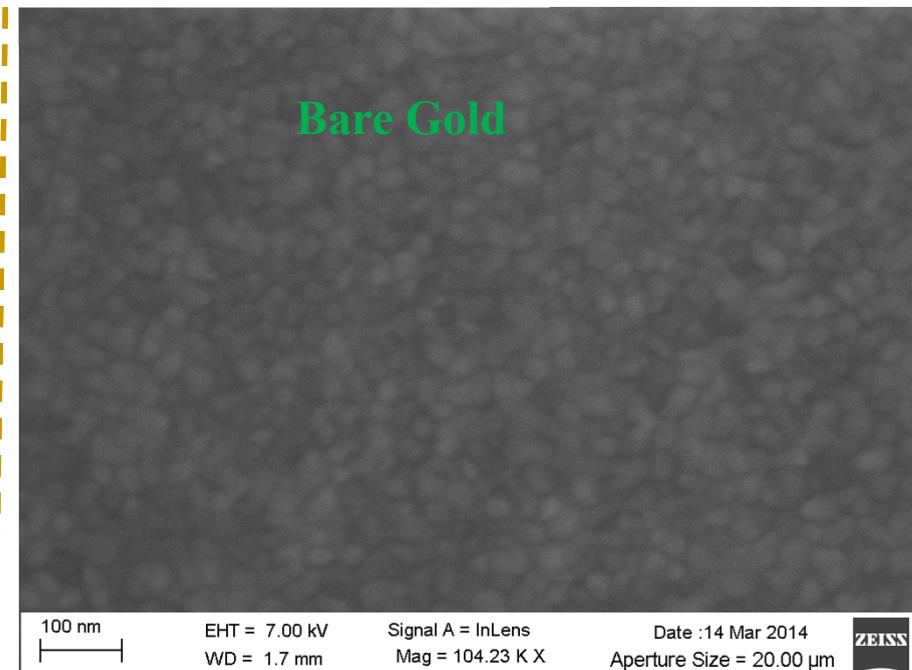
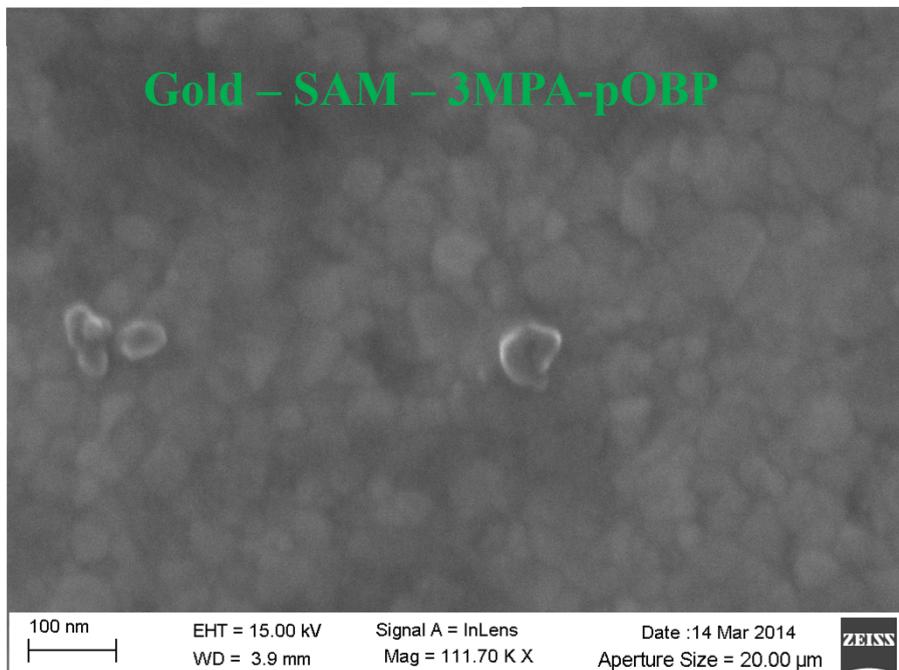
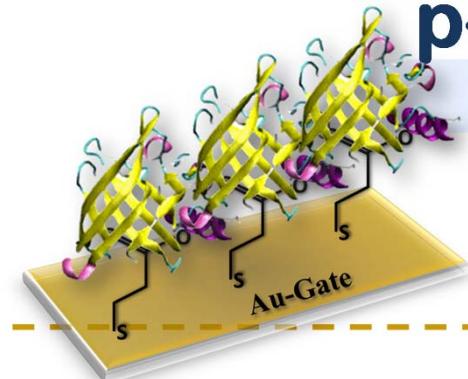
OBP in a water gated OFET sensor



M. Y. Mulla

Mulla, M.Y. et al. *Nature Communications*, 2015, 6, 6010

p-OBP SAM SEM surface topography

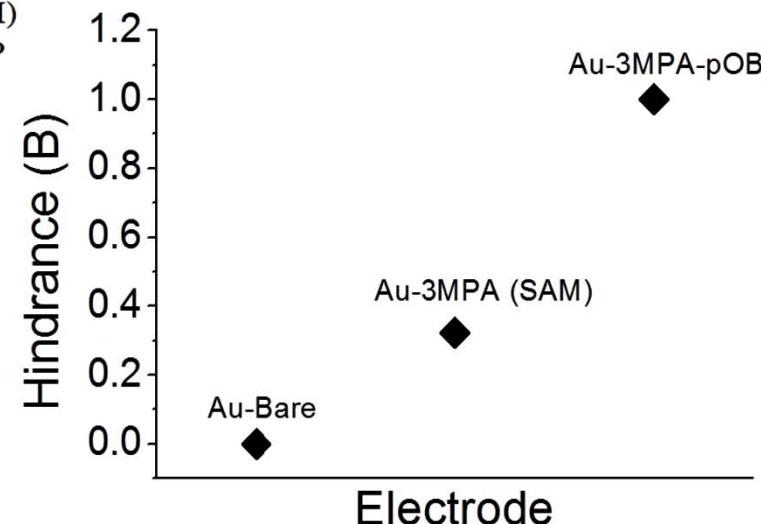
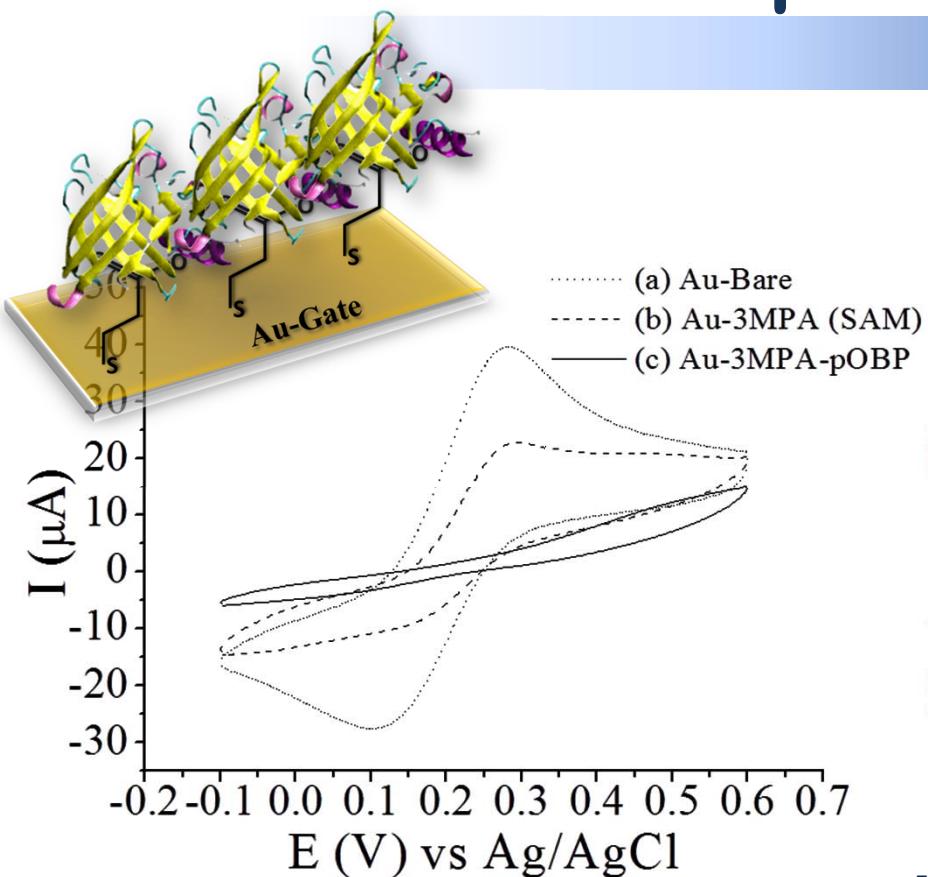


Cinzia Di Franco - CNR - Bari
Maria Vittoria Santacroce and Gaetano Scamarcio - University of Bari

Mulla, M.Y. et al. *Nature Communications*, 2015, 6, 6010

Luisa Torsi - Università degli Studi di Bari “Aldo Moro” (Italy)

Electrochemical pOBP SAM characterization



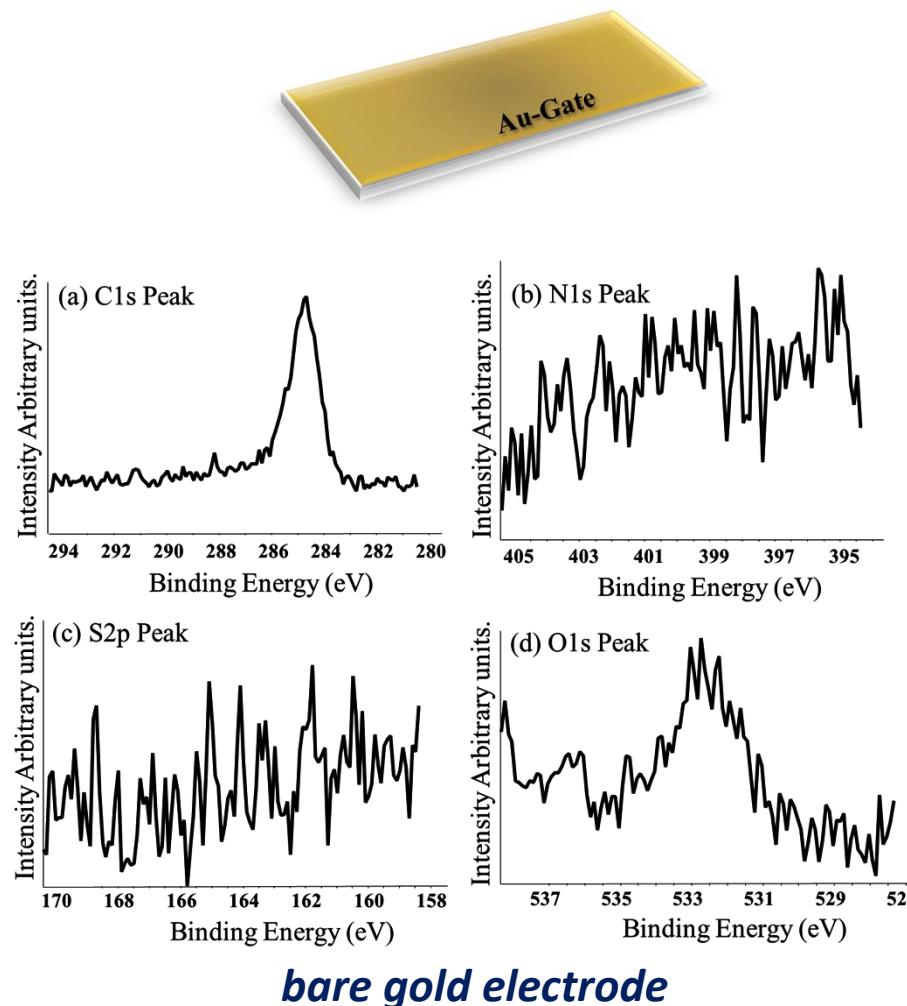
$$B = 1 - \left(\frac{I_0^{\text{Fun}}}{I_0^{\text{Au}}} \right)$$

Where, I_0^{Fun} and I_0^{Au} are the oxidative peak currents obtained from the CV curves for functionalized electrode (3MPA alone and 3MPA-pOBP) and the bare Au electrode respectively

$\text{K}_4\text{Fe}(\text{CN})_6$ electro-active

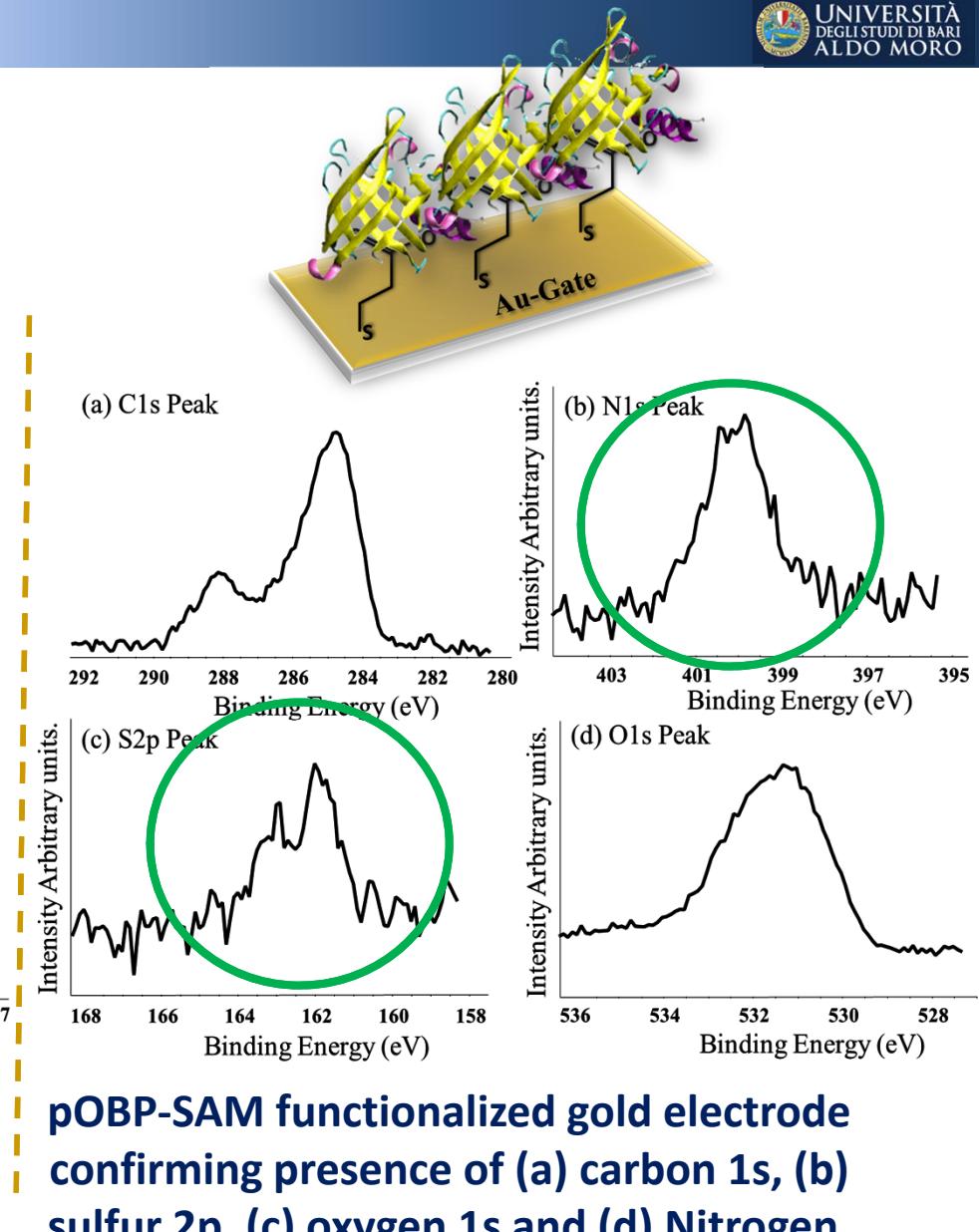


XPS pOBP SAM characterization



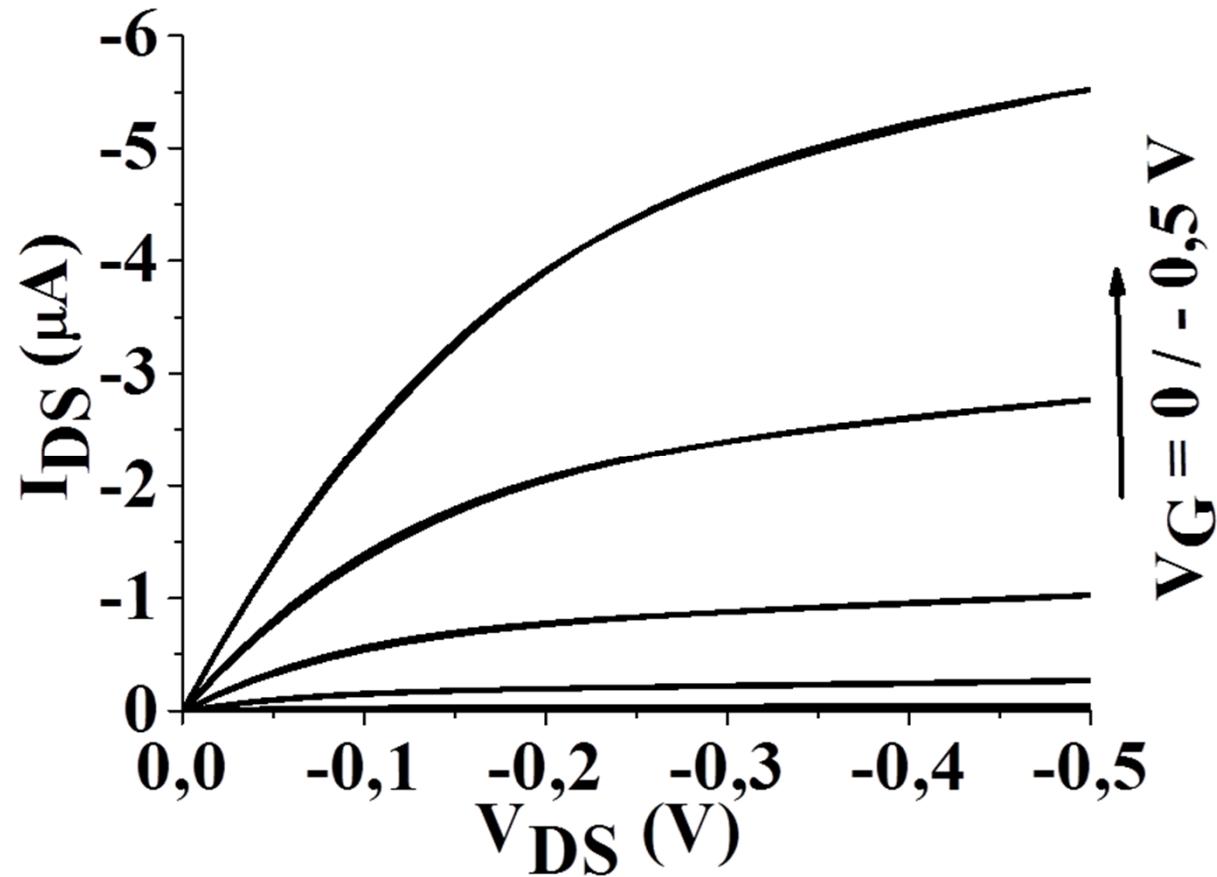
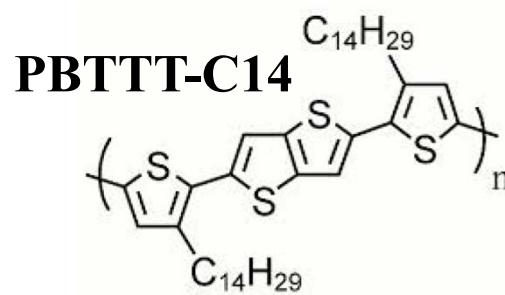
bare gold electrode

Dr. Nicoletta Di Taranto



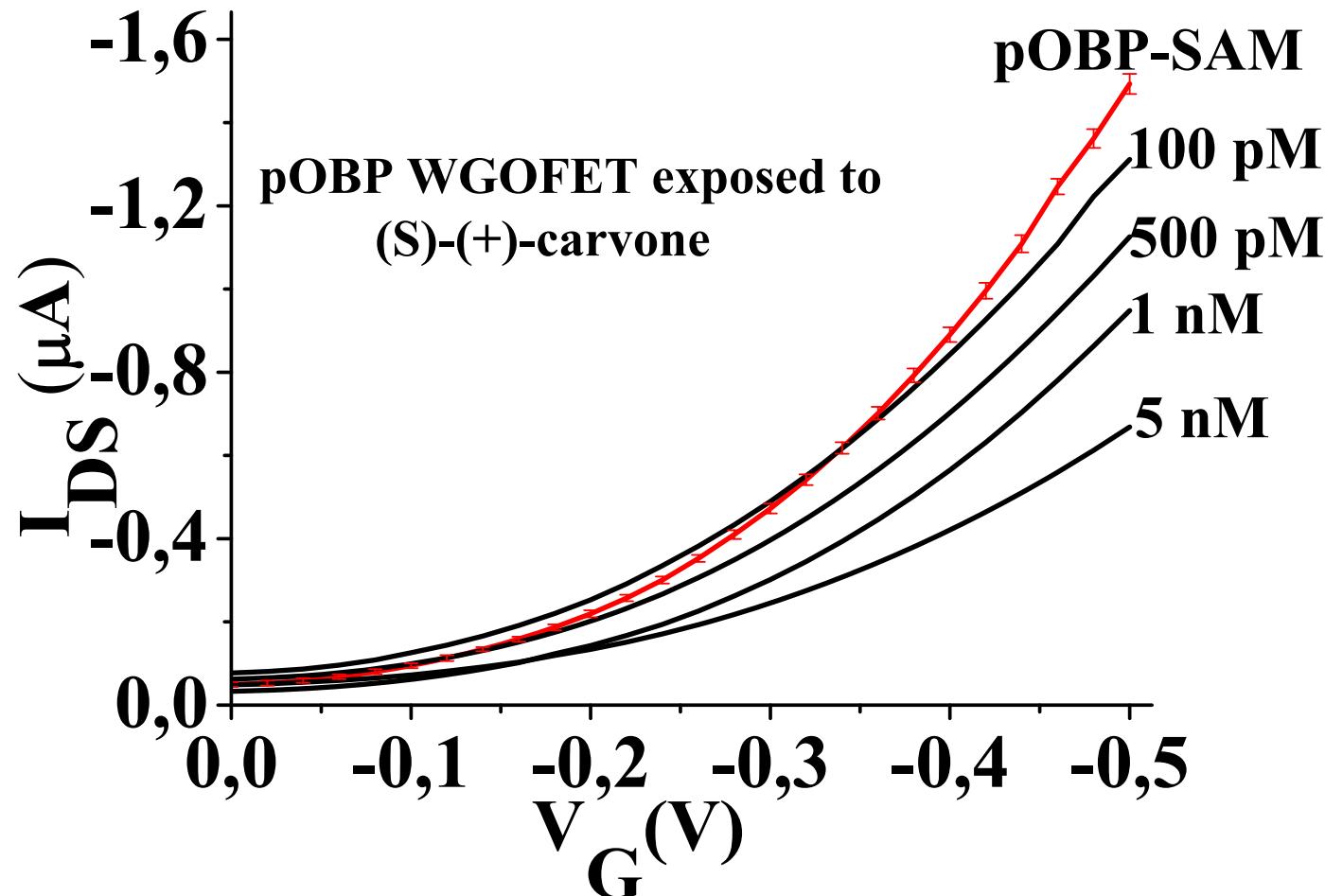
**pOBP-SAM functionalized gold electrode
confirming presence of (a) carbon 1s, (b)
sulfur 2p, (c) oxygen 1s and (d) Nitrogen.**

I-V Characteristics

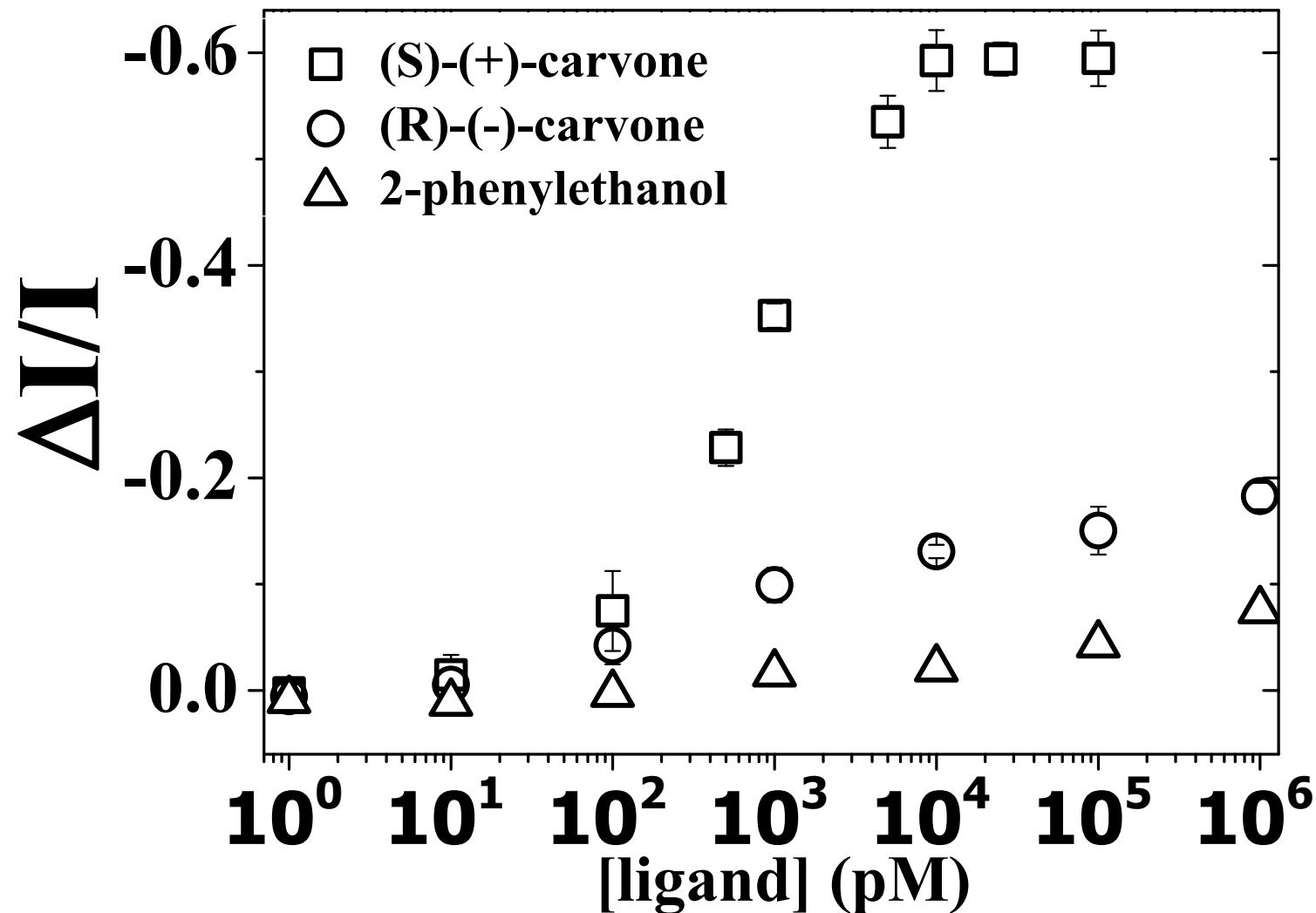


$V_T = -0.01 \pm 0.06$ V, *on/off* current ratio of 150 ± 110 and
 $\mu_{FET} = 1.1 \pm 0.2 \ 10^{-1} \text{ cm}^2/\text{Vs}$.

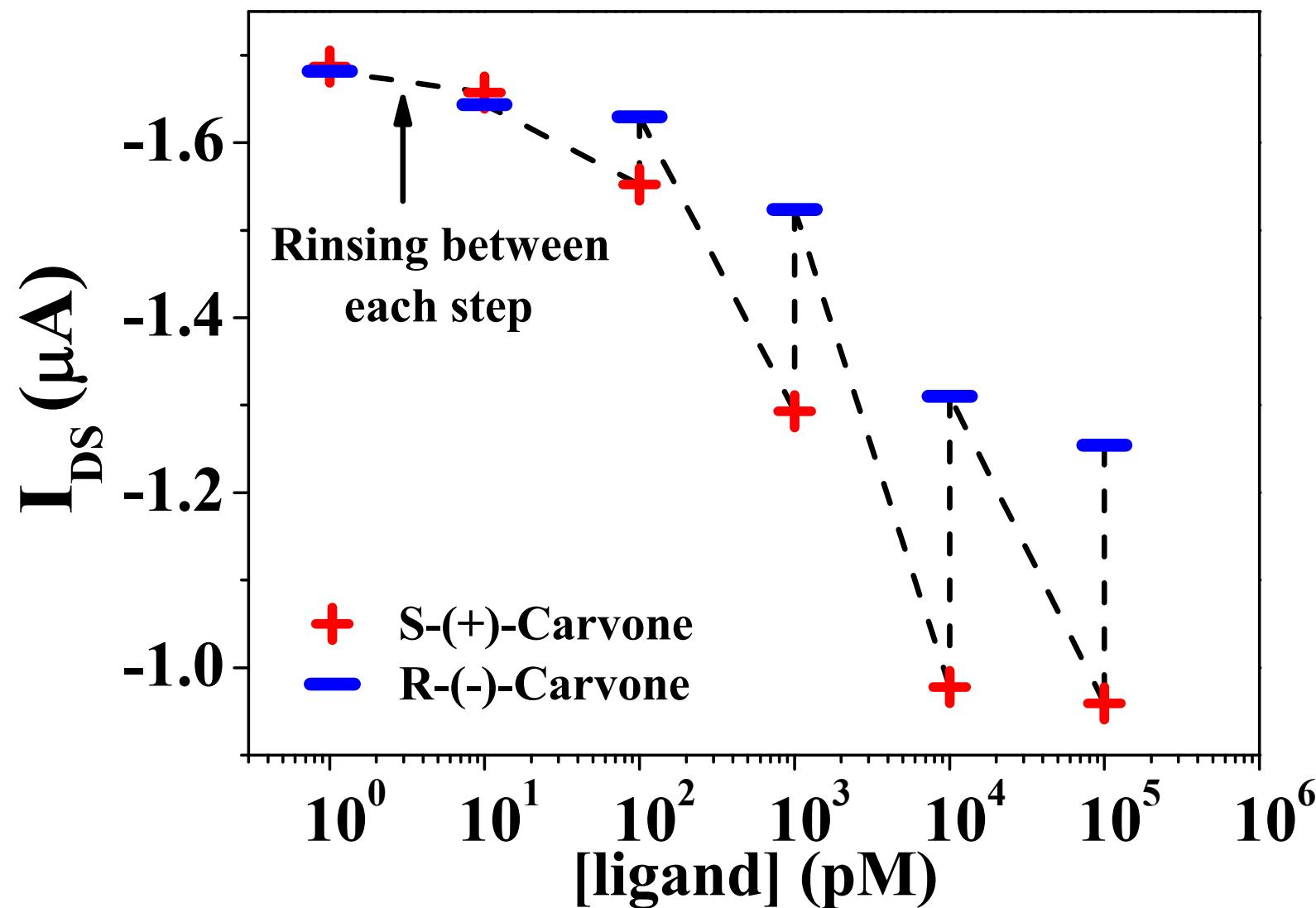
Sensing of tine neutral species with WGOFETs



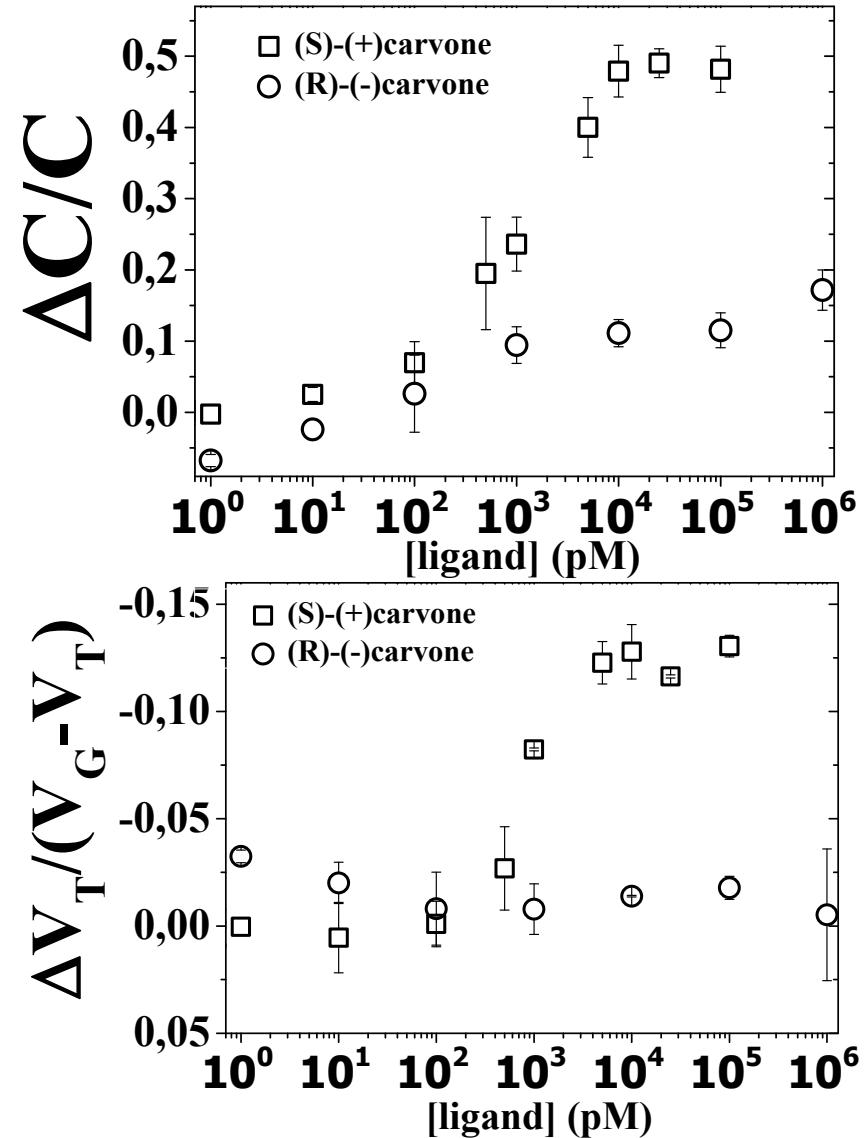
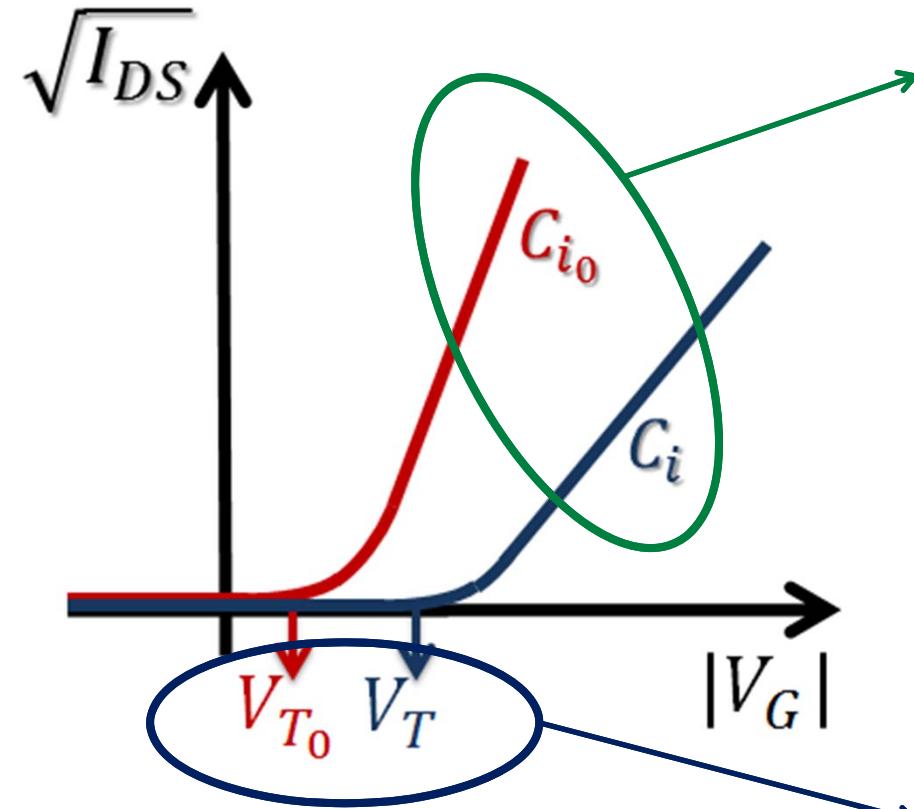
dose-curves with WGOFETs



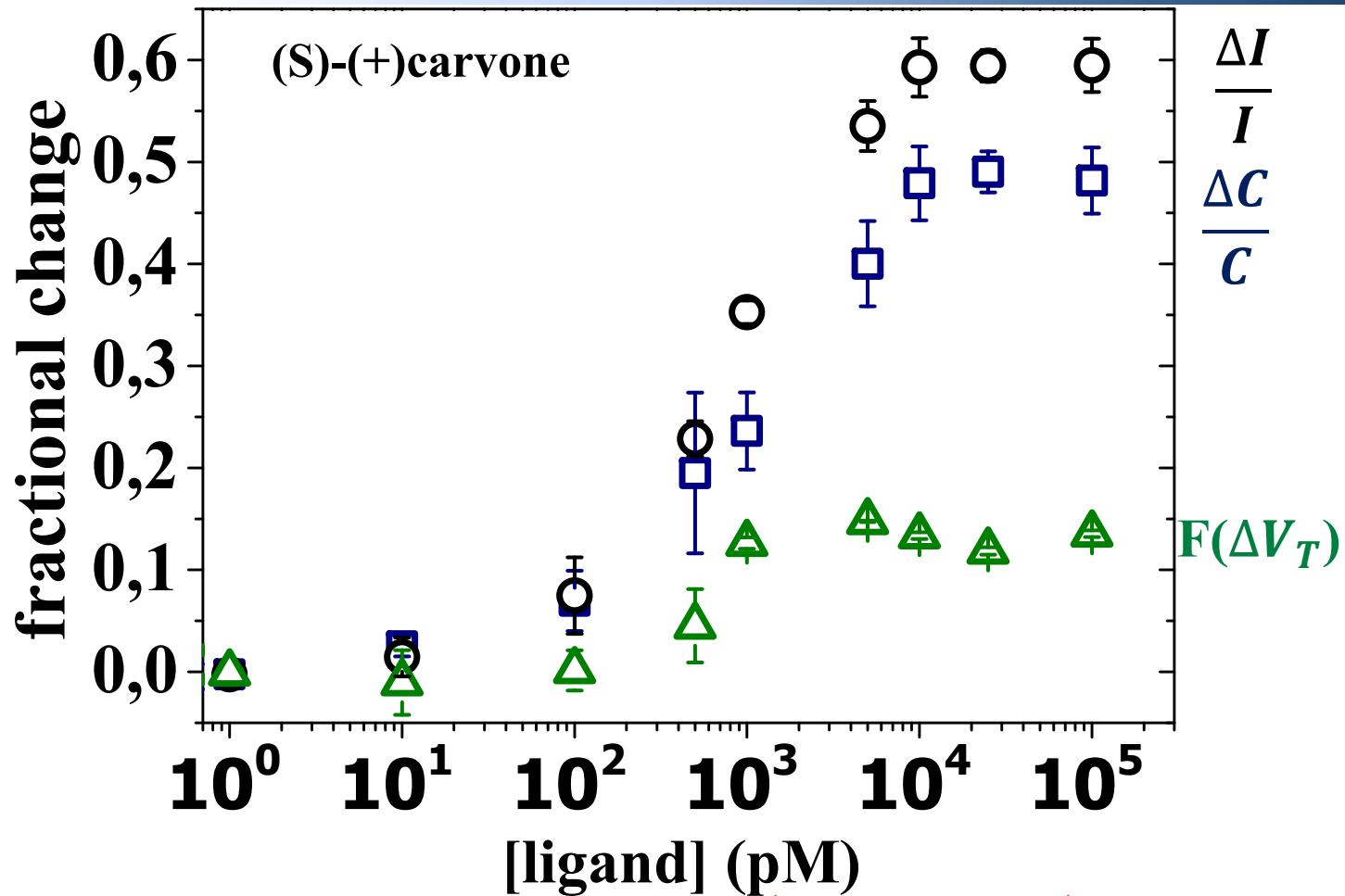
the two enantiomers on the very same gate



Decoupling capacitance and threshold voltage

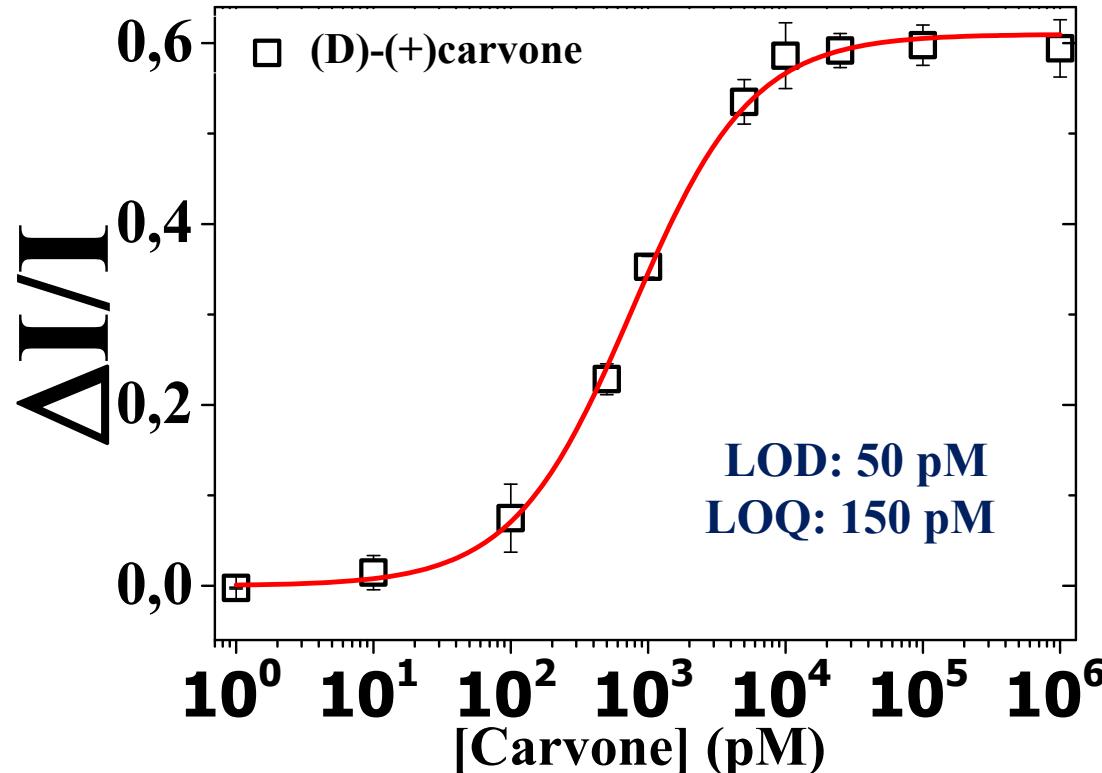


The response is dominated by capacitance



$$\frac{\Delta I}{I} \approx \frac{\Delta C_i}{C_i}$$

(S)-(+)-carvone / pOBP complex



single-site
Langmuir's isotherm

$$\frac{\Delta I}{I} = b_{MAX} \frac{[carv]}{K_{FET} + [carv]}$$

$K_{FET}^{(+)}$ of $0.81 \pm 0.05 \text{ nM}$
 $\Delta I/I^{(+)}$ as high as -60%; LOD: 50 pM



electronic OFET Bilayer configuration

A sensitivity-enhanced field-effect chiral sensor

LUISA TORSI^{1,2*}, GIANLUCA M. FARINOLA¹, FRANCESCO MARINELLI¹, M. CRISTINA TANESE¹, OMAR HASSAN OMAR³, LUDOVICO VALLI⁴, FRANCESCO BABUDRI^{1,3}, FRANCESCO PALMISANO^{1,2}, P. GIORGIO ZAMBONIN^{1,2} AND FRANCESCO NASO^{1,3*}

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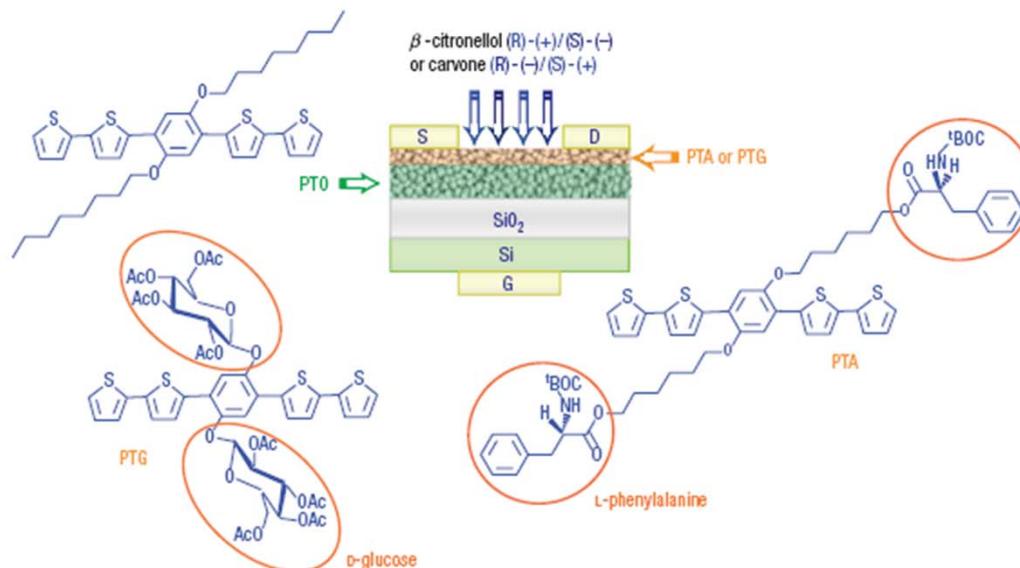


Figure 1 Bilayer OTFT chiral sensor structure. The transistor has a bottom-gate device structure that consists of a highly n-doped silicon wafer (resistivity 0.02–1 Ω cm $^{-1}$)

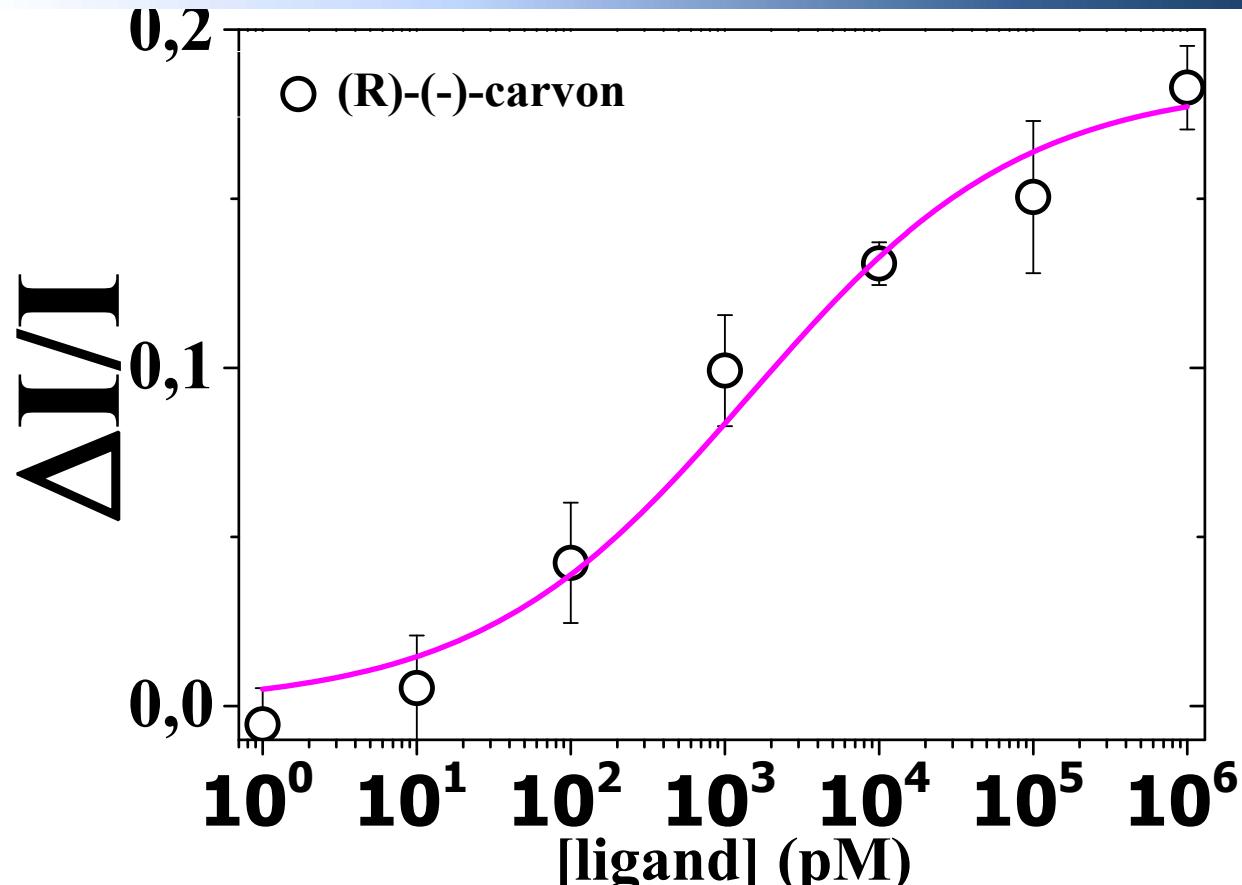
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(R)-(-)carvone / pOBP complex

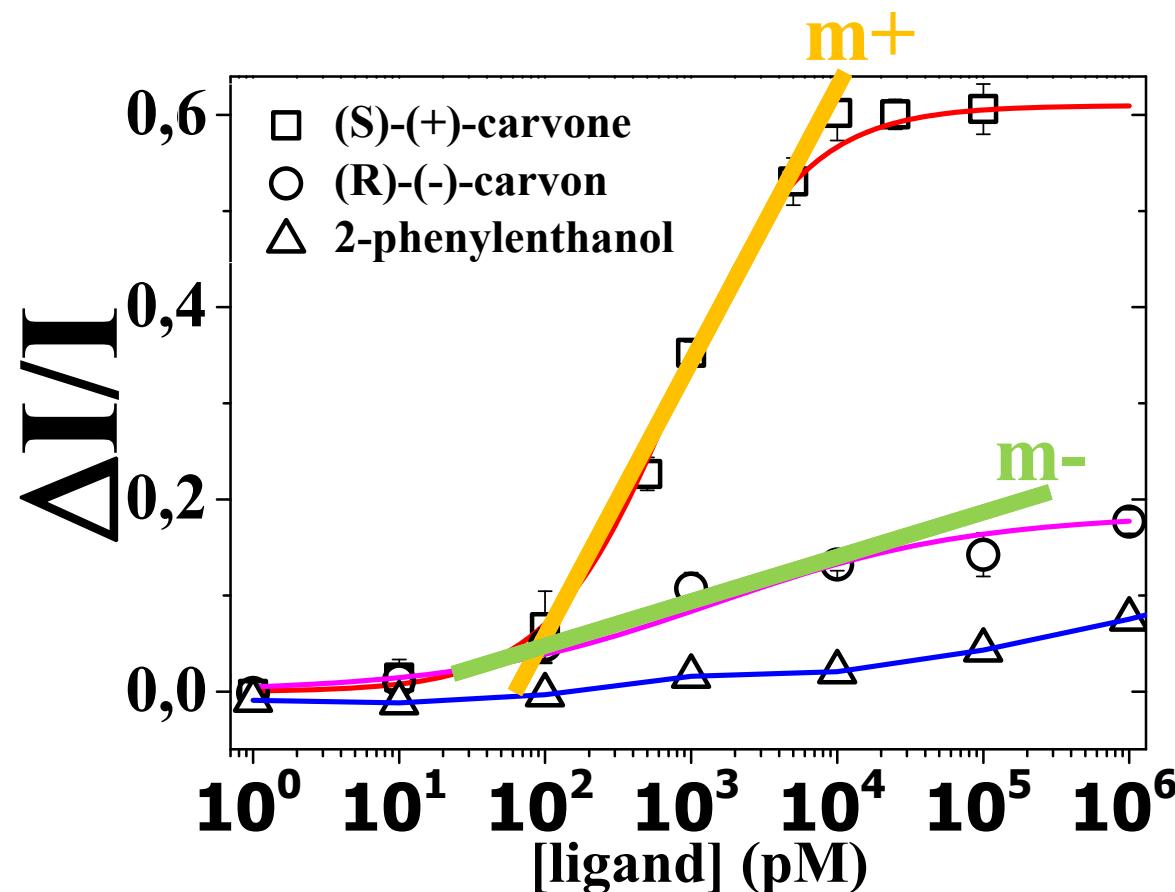


Hill's isotherm $\frac{\Delta I}{I} = b_{MAX} \frac{[carv]^\alpha}{K_{FET} + [carv]^\alpha}$
 α : level of cooperative

$K_{FET}^{(-)}$ of 20 ± 20 nM

$\Delta I/I^{(+)}$ of - 17 % ($\alpha = 0.5 \rightarrow$ non-cooperative binding)

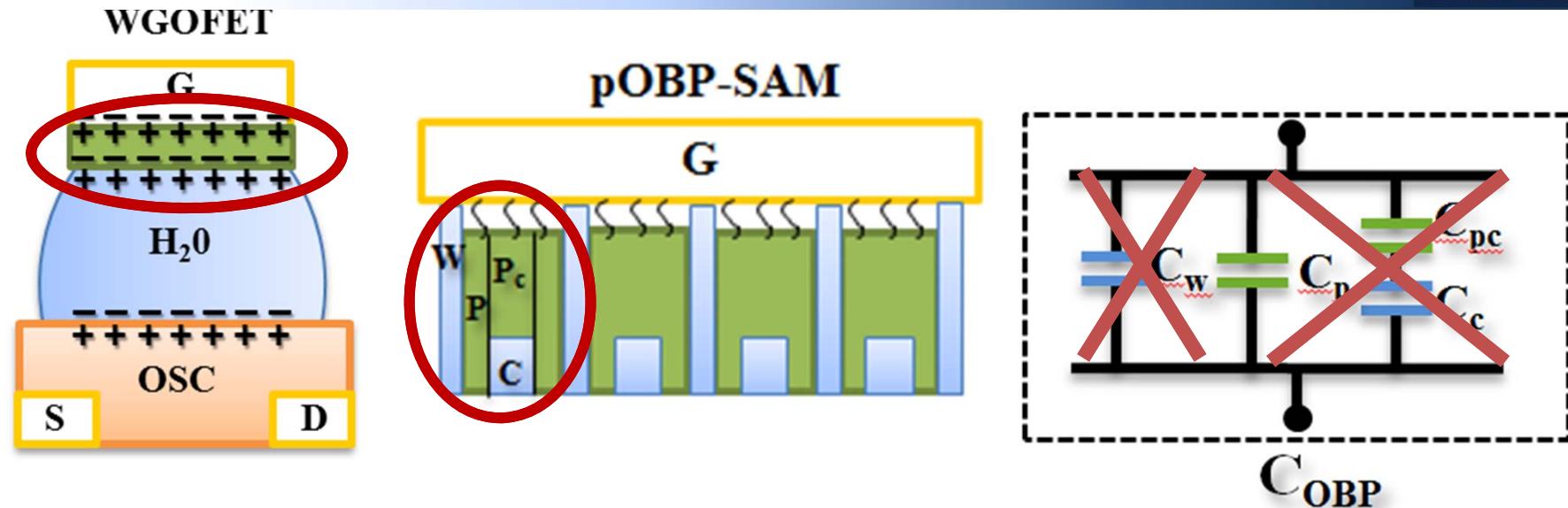
enanthio-selectivity factor > 6



$$\text{ESF} = m+/m- = 6.3$$

markedly different levels of cooperativity and an exceptionally high ESF

The pOBP capacitance model



2.4 % of the total surface of the protein exposed to the solvent ($\sim 7 \text{ nm}^2$) it well accommodate a few water molecules

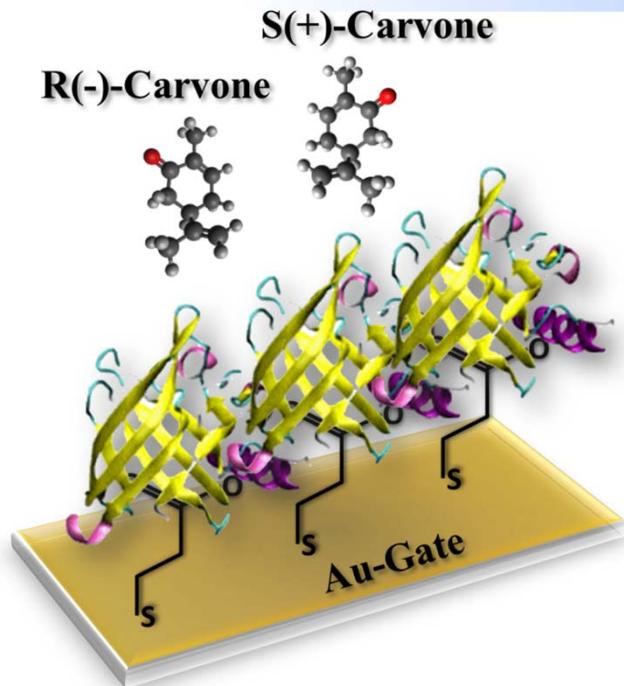


G. Lattanzi



high dielectric percolative path, “water channel”

dissociation constant for 2D receptors



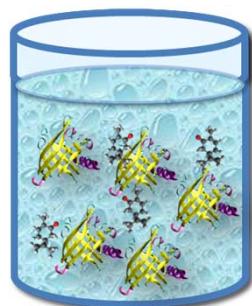
$$\Delta G^0 = RT \ln[K_D]$$

Surface segregated OBP

$$\Delta G^{\circ}_{\text{FET}}{}^{(+)} = - (49.2 \pm 0.1) \text{ kJ/mol}$$

$$\Delta G^{\circ}_{\text{FET}}{}^{(-)} = -(41 \pm 2) \text{ kJ/mol}$$

OBP in solution

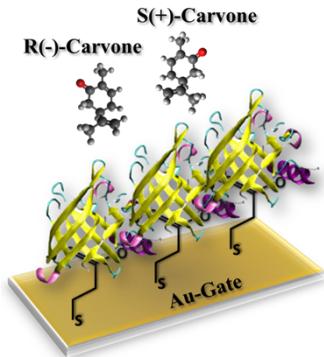


$$\Delta G^{\circ}_{\text{sol}}{}^{(+)} = - (36.00 \pm 0.05) \text{ kJ/mol}$$

$$\Delta G^{\circ}_{\text{sol}}{}^{(-)} = - (33.0 \pm 0.1) \text{ kJ/mol}$$

the thermodynamic cycle

L = carvones



P = pOBP

e = gate free-electrons

P-L=complex

L (sol) + P (gate)

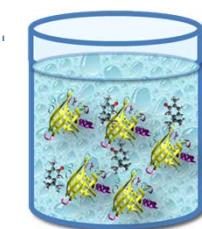
P-L(gate) + e(P-L)

$-\Delta_{\text{imm}}G(P) - \bar{\mu}_e(P)$

$\Delta_{\text{imm}}G(P-L) + \bar{\mu}_e(P-L)$

L (sol) + e

P-L (sol)



$$\Delta G_{FET}^0 = \Delta G_{Sol}^0 + \Delta E_F + W$$

$$\Delta E_F = (\bar{\mu}_e(P-L) - \bar{\mu}_e(P)) = -nF\Delta V_T$$

$$W = \Delta_{\text{imm}}G(P-L) - \Delta_{\text{imm}}G(P)$$

binding surface work - surface tension

Financial support



Laboratorio
SISTEMA



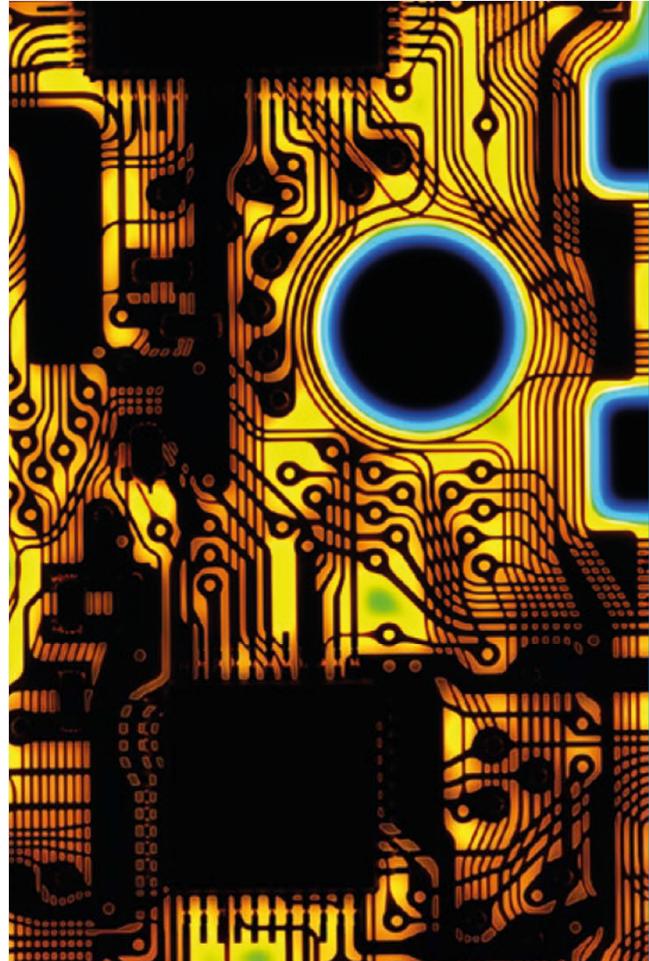
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team & principal collaborations

Thanks



L. Sabbatini



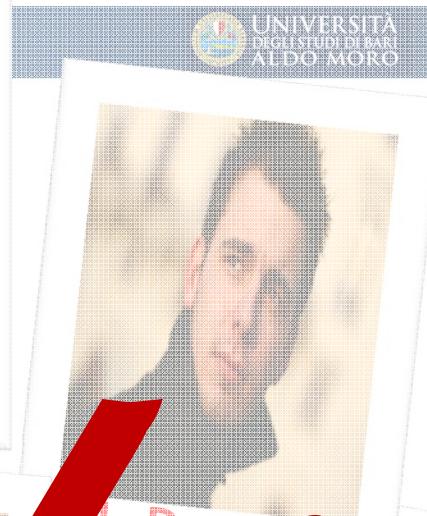
L. Torsi



G. Palazzo



Consiglio
Nazionale
Ricerca



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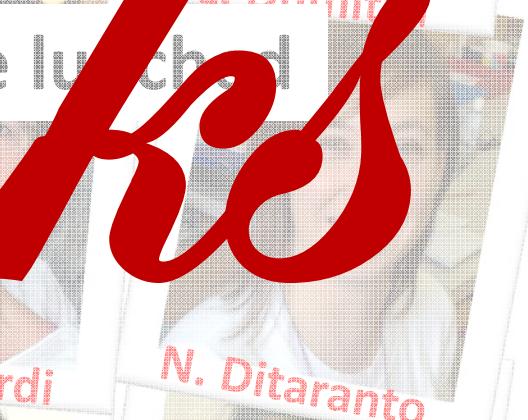
M. Singh



N. Cioffi



M. Y. Mulla



A. Mallardi



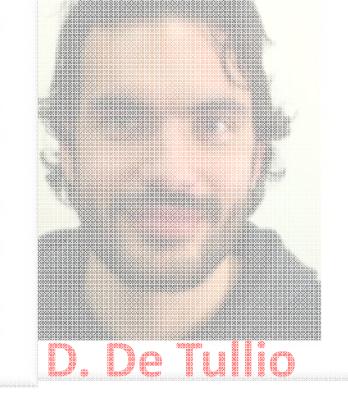
E. Macchia



G. Scamarcio



F. De Noto



D. De Tullio



K. Manoli

Post-doc positions in October will be launched

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